

RF Power LDMOS Transistors

High Ruggedness N-Channel Enhancement-Mode Lateral MOSFETs

Designed for mobile two-way radio applications with frequencies from 136 to 520 MHz. The high gain, ruggedness and broadband performance of these devices make them ideal for large-signal, common source amplifier applications in mobile radio equipment.

Typical Performance: (13.6 Vdc, $T_A = 25^\circ\text{C}$, CW)

| Frequency (MHz) | G_{ps} (dB) | η_D (%) | P1dB (W) |
|-----------------|---------------|--------------|----------|
| 136-174 (1,4) | 23.2 | 62.0 | 31 |
| 380-450 (2,4) | 18.3 | 64.1 | 31 |
| 450-520 (3,4) | 17.7 | 62.0 | 31 |
| 520 (5) | 17.7 | 71.4 | 33 |

Load Mismatch/Ruggedness

| Frequency (MHz) | Signal Type | VSWR | P_{in} (W) | Test Voltage | Result |
|-----------------|-------------|---------------------------|--------------------------|--------------|-----------------------|
| 155 (1) | CW | >65:1 at all Phase Angles | 0.55 (3 dB Overdrive) | 17 | No Device Degradation |
| 420 (2) | | | 1.6 (3 dB Overdrive) | | |
| 490 (3) | | | 2.0 (3 dB Overdrive) | | |
| 520 (5) | | | 1.1 (3 dB Overdrive) | | |

1. Measured in 136-174 MHz VHF broadband reference circuit.
2. Measured in 380-450 MHz UHF broadband reference circuit.
3. Measured in 450-520 MHz UHF broadband reference circuit.
4. The values shown are the minimum measured performance numbers across the indicated frequency range.
5. Measured in 520 MHz narrowband test circuit.

Features

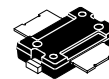
- Characterized for Operation from 136 to 520 MHz
- Unmatched Input and Output Allowing Wide Frequency Range Utilization
- Integrated ESD Protection
- Integrated Stability Enhancements
- Wideband — Full Power Across the Band:
 - 136-174 MHz
 - 380-450 MHz
 - 450-520 MHz
- 225°C Capable Plastic Package
- Exceptional Thermal Performance
- High Linearity for: TETRA, SSB, LTE
- Cost-effective Over-molded Plastic Packaging
- In Tape and Reel. R1 Suffix = 500 Units, 24 mm Tape Width, 13 inch Reel.

Typical Applications

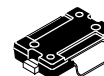
- Output Stage VHF Band Mobile Radio
- Output Stage UHF Band Mobile Radio

AFT05MS031NR1
AFT05MS031GNR1

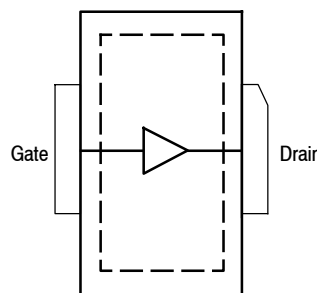
136-520 MHz, 31 W, 13.6 V
WIDEBAND
RF POWER LDMOS TRANSISTORS



**TO-270-2
PLASTIC
AFT05MS031NR1**



**TO-270-2 GULL
PLASTIC
AFT05MS031GNR1**



(Top View)

Note: The backside of the package is the source terminal for the transistor.

Figure 1. Pin Connections

Table 1. Maximum Ratings

| Rating | Symbol | Value | Unit |
|--|-----------|-------------|-----------|
| Drain-Source Voltage | V_{DSS} | -0.5, +40 | Vdc |
| Gate-Source Voltage | V_{GS} | -6.0, +12 | Vdc |
| Operating Voltage | V_{DD} | 17, +0 | Vdc |
| Storage Temperature Range | T_{stg} | -65 to +150 | °C |
| Case Operating Temperature Range | T_C | -40 to +150 | °C |
| Operating Junction Temperature Range (1,2) | T_J | -40 to +225 | °C |
| Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C | P_D | 294 1.47 | W W/°C |

Table 2. Thermal Characteristics

| Characteristic | Symbol | Value (2,3) | Unit |
|--|-----------------|-------------|------|
| Thermal Resistance, Junction to Case Case Temperature 79°C , 31 W CW, 13.6 Vdc, $I_{DQ} = 10$ mA, 520 MHz | $R_{\theta JC}$ | 0.67 | °C/W |

Table 3. ESD Protection Characteristics

| Test Methodology | Class |
|---------------------------------------|-------------------|
| Human Body Model (per JESD22-A114) | 2, passes 2500 V |
| Machine Model (per EIA/JESD22-A115) | A, passes 100 V |
| Charge Device Model (per JESD22-C101) | IV, passes 2000 V |

Table 4. Moisture Sensitivity Level

| Test Methodology | Rating | Package Peak Temperature | Unit |
|--------------------------------------|--------|--------------------------|------|
| Per JESD22-A113, IPC/JEDEC J-STD-020 | 3 | 260 | °C |

Table 5. Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

Off Characteristics

| | | | | | |
|---|-----------|---|---|-----|-----------------|
| Zero Gate Voltage Drain Leakage Current ($V_{DS} = 40$ Vdc, $V_{GS} = 0$ Vdc) | I_{DSS} | — | — | 2 | μAdc |
| Zero Gate Voltage Drain Leakage Current ($V_{DS} = 13.6$ Vdc, $V_{GS} = 0$ Vdc) | I_{DSS} | — | — | 1 | μAdc |
| Gate-Source Leakage Current ($V_{GS} = 5$ Vdc, $V_{DS} = 0$ Vdc) | I_{GSS} | — | — | 600 | nAdc |

On Characteristics

| | | | | | |
|--|--------------|-----|------|-----|-----|
| Gate Threshold Voltage ($V_{DS} = 10$ Vdc, $I_D = 115$ μAdc) | $V_{GS(th)}$ | 1.6 | 2.1 | 2.6 | Vdc |
| Drain-Source On-Voltage ($V_{GS} = 10$ Vdc, $I_D = 1.2$ Adc) | $V_{DS(on)}$ | — | 0.13 | — | Vdc |
| Forward Transconductance ($V_{DS} = 10$ Vdc, $I_D = 7.5$ Adc) | g_{fs} | — | 5.8 | — | S |

1. Continuous use at maximum temperature will affect MTTF.
2. MTTF calculator available at <http://www.freescale.com/rf>. Select Software & Tools/Development Tools/Calculators to access MTTF calculators by product.
3. Refer to AN1955, *Thermal Measurement Methodology of RF Power Amplifiers*. Go to <http://www.freescale.com/rf>. Select Documentation/Application Notes - AN1955.

(continued)

Table 5. Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted) (continued)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|--|-------------|---------------------------|-------------------------|------------------------|-----------------------|
| Dynamic Characteristics | | | | | |
| Reverse Transfer Capacitance ($V_{DS} = 13.6\text{ Vdc} \pm 30\text{ mV(rms)ac}$ @ 1 MHz, $V_{GS} = 0\text{ Vdc}$) | C_{rss} | — | 1.6 | — | pF |
| Output Capacitance ($V_{DS} = 13.6\text{ Vdc} \pm 30\text{ mV(rms)ac}$ @ 1 MHz, $V_{GS} = 0\text{ Vdc}$) | C_{oss} | — | 49.5 | — | pF |
| Input Capacitance ($V_{DS} = 13.6\text{ Vdc}$, $V_{GS} = 0\text{ Vdc} \pm 30\text{ mV(rms)ac}$ @ 1 MHz) | C_{iss} | — | 109 | — | pF |
| Functional Tests ⁽¹⁾ (In Freescale Narrowband Test Fixture, 50 ohm system) $V_{DD} = 13.6\text{ Vdc}$, $I_{DQ} = 10\text{ mA}$, $P_{out} = 31\text{ W}$, $f = 520\text{ MHz}$ | | | | | |
| Common-Source Amplifier Power Gain | G_{ps} | 16.5 | 17.7 | 19.0 | dB |
| Drain Efficiency | η_D | 70.0 | 71.4 | — | % |
| Load Mismatch/Ruggedness (In Freescale Test Fixture, 50 ohm system) $I_{DQ} = 10\text{ mA}$ | | | | | |
| Frequency (MHz) | Signal Type | VSWR | P_{in} (W) | Test Voltage, V_{DD} | Result |
| 520 | CW | >65:1 at all Phase Angles | 1.1 (3 dB Overdrive) | 17 | No Device Degradation |

1. Measurements made with device in straight lead configuration before any lead forming operation is applied. Lead forming is used for gull wing (GN) parts.

TYPICAL CHARACTERISTICS

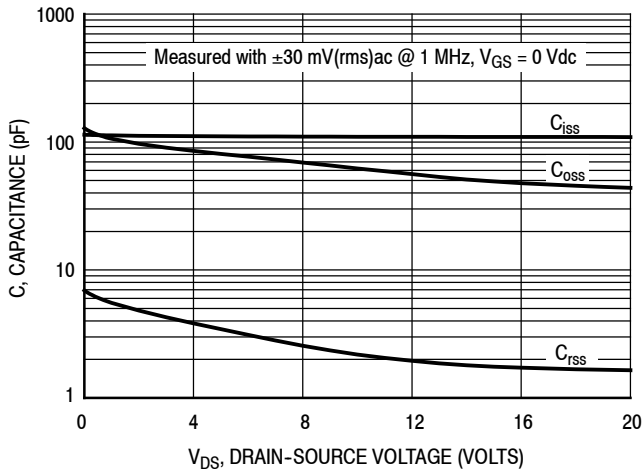


Figure 2. Capacitance versus Drain-Source Voltage

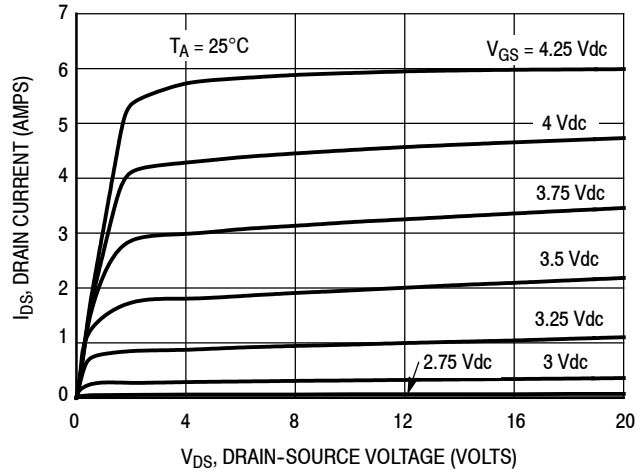
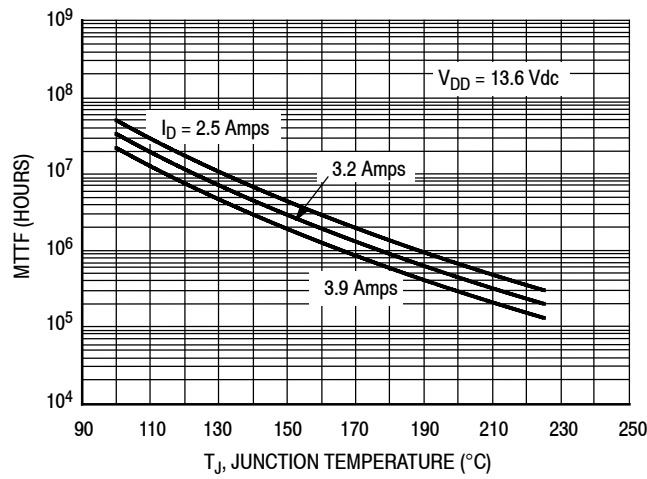


Figure 3. Drain Current versus Drain-Source Voltage



Note: MTTF value represents the total cumulative operating time under indicated test conditions.

MTTF calculator available at <http://www.freescale.com/rf>. Select Software & Tools/Development Tools/Calculators to access MTTF calculators by product.

Figure 4. MTTF versus Junction Temperature - CW

520 MHz NARROWBAND PRODUCTION TEST FIXTURE

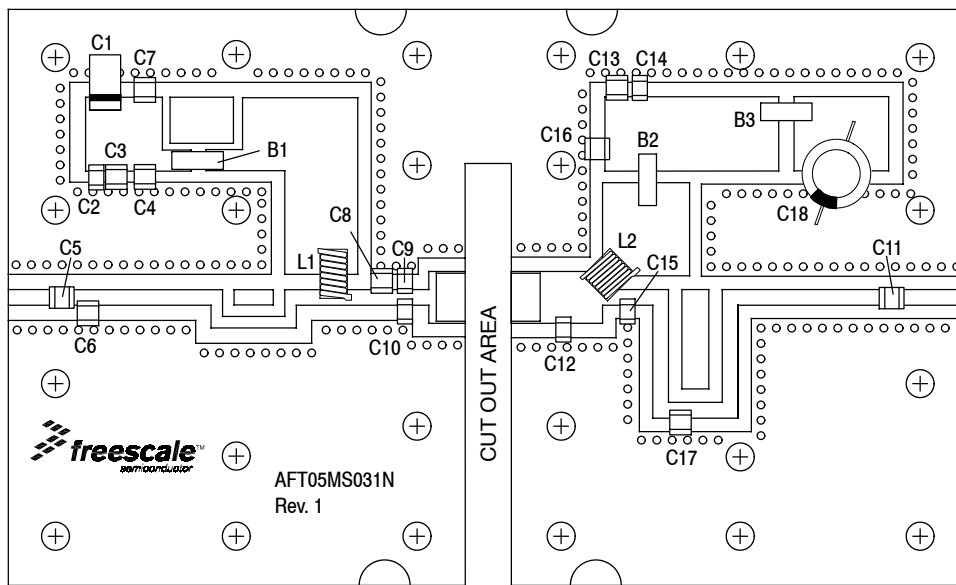


Figure 5. AFT05MS031NR1 Narrowband Test Circuit Component Layout — 520 MHz

Table 6. AFT05MS031NR1 Narrowband Test Circuit Component Designations and Values — 520 MHz

| Part | Description | Part Number | Manufacturer |
|-------------------|--|-------------------|------------------|
| B1, B2, B3 | RF Beads, Long | 2743021447 | Fair-Rite |
| C1 | 22 μ F, 35 V Tantalum Capacitor | T491X226K035AT | Kemet |
| C2, C14 | 0.01 μ F Chip Capacitors | C0805C103K5RAC | Kemet |
| C3, C13 | 0.1 μ F Chip Capacitors | CDR33BX104AKWS | Kemet |
| C4 | 200 pF Chip Capacitor | ATC100B201JT300XT | ATC |
| C5 | 6.2 pF Chip Capacitor | ATC100B6R2JT500XT | ATC |
| C6 | 3.9 pF Chip Capacitor | ATC100B3R9JT500XT | ATC |
| C7, C16 | 180 pF Chip Capacitors | ATC100B181JT200XT | ATC |
| C8 | 10 pF Chip Capacitor | ATC100B100JT500XT | ATC |
| C9, C10, C11, C12 | 36 pF Chip Capacitors | ATC100B360JT500XT | ATC |
| C15 | 27 pF Chip Capacitor | ATC100B270JT500XT | ATC |
| C17 | 7.5 pF Chip Capacitor | ATC100B7R5JT500XT | ATC |
| C18 | 470 μ F, 63 V Electrolytic Capacitor | SME63V471M12X25LL | United Chemi-Con |
| L1 | 43 nH, 10 Turn Inductor | B10TJLC | Coilcraft |
| L2 | 56 nH Inductor | 1812SMS-56NJLC | Coilcraft |
| PCB | 0.030", $\epsilon_r = 2.55$ | AD255A | Arlon |

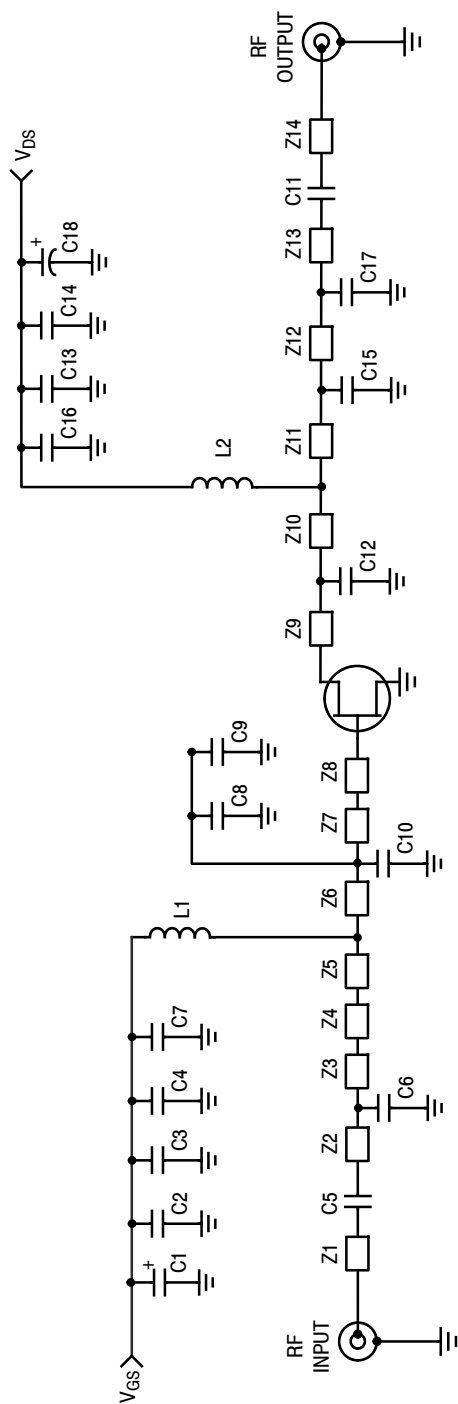


Figure 6. AFT05MS031NR1 Narrowband Test Circuit Schematic — 520 MHz

Table 7. AFT05MS031NR1 Narrowband Test Circuit Microstrips — 520 MHz

| Microstrip | Description | Microstrip | Description |
|------------|----------------------------|------------|-----------------------------|
| Z1 | 0.199" x 0.082" Microstrip | Z8 | 0.190" x 0.270" Microstrip |
| Z2 | 0.017" x 0.082" Microstrip | Z9 | 0.257" x 0.275" Microstrip |
| Z3* | 0.670" x 0.082" Microstrip | Z10 | 0.145" x 0.275" Microstrip |
| Z4* | 0.560" x 0.060" Microstrip | Z11 | 0.091" x 0.082" Microstrip |
| Z5* | 0.370" x 0.082" Microstrip | Z12* | 0.1322" x 0.082" Microstrip |
| Z6 | 0.079" x 0.082" Microstrip | Z13* | 0.1420" x 0.082" Microstrip |
| Z7 | 0.352" x 0.082" Microstrip | Z14 | 0.315" x 0.082" Microstrip |

* Line length includes microstrip bends

TYPICAL CHARACTERISTICS — 520 MHz

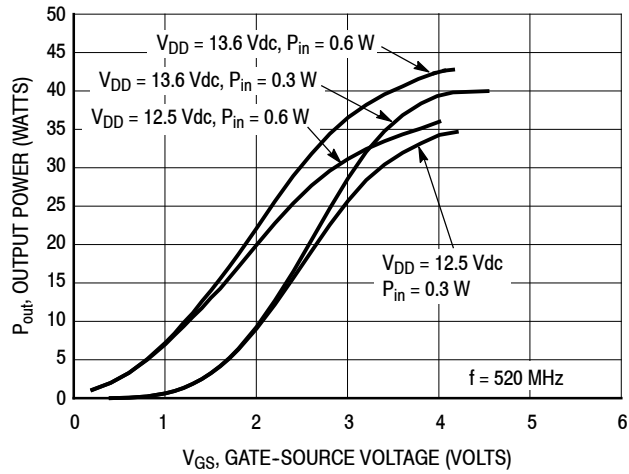


Figure 7. Output Power versus Gate-Source Voltage

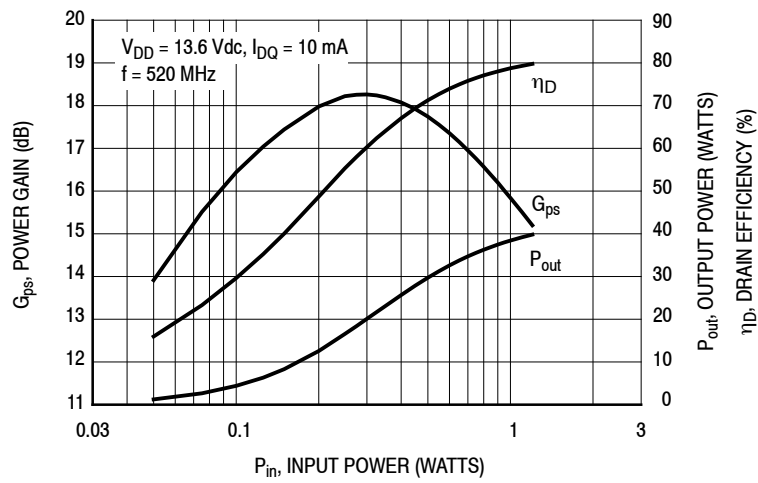


Figure 8. Power Gain, Output Power and Drain Efficiency versus Input Power

$V_{DD} = 13.6 \text{ Vdc}$, $I_{DQ} = 10 \text{ mA}$, $P_{out} = 31 \text{ W Avg.}$

| f MHz | Z_{source} Ω | Z_{load} Ω |
|----------|-------------------|-----------------|
| 520 | $0.72 + j1.77$ | $1.54 + j0.80$ |

Z_{source} = Test circuit impedance as measured from gate to ground.

Z_{load} = Test circuit impedance as measured from drain to ground.

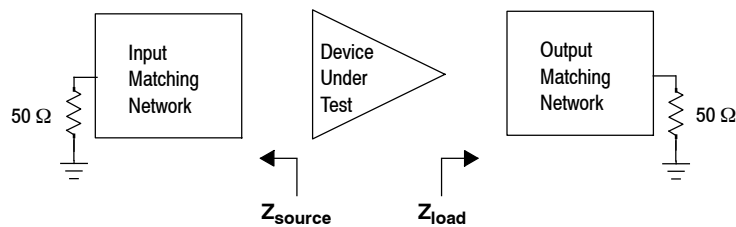


Figure 9. Narrowband Series Equivalent Source and Load Impedance — 520 MHz

136-174 MHz VHF BROADBAND REFERENCE CIRCUIT

Table 8. 136-174 MHz VHF Broadband Performance (In Freescale Reference Circuit, 50 ohm system)
 $V_{DD} = 13.6$ Volts, $I_{DQ} = 100$ mA, $T_A = 25^\circ\text{C}$, CW

| Frequency (MHz) | G_{ps} (dB) | η_D (%) | P1dB (W) |
|-----------------|---------------|--------------|----------|
| 136 | 25.0 | 64.0 | 31 |
| 155 | 23.2 | 63.0 | 31 |
| 174 | 23.2 | 62.0 | 31 |

Table 9. Load Mismatch/Ruggedness (In Freescale Reference Circuit)

| Frequency (MHz) | Signal Type | VSWR | P_{in} (W) | Test Voltage, V_{DD} | Result |
|-----------------|-------------|---------------------------|-----------------------|------------------------|-----------------------|
| 155 | CW | >65:1 at all Phase Angles | 0.55 (3 dB Overdrive) | 17 | No Device Degradation |

136-174 MHz VHF BROADBAND REFERENCE CIRCUIT

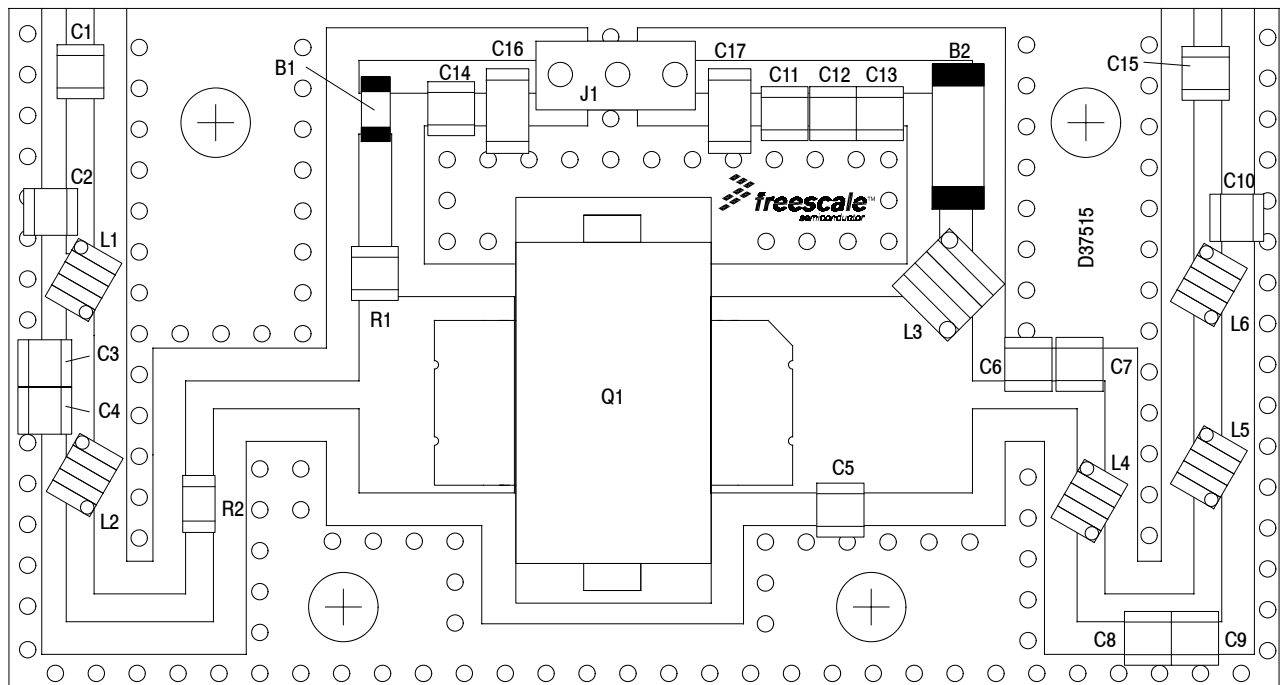


Figure 10. AFT05MS031NR1 VHF Broadband Reference Circuit Component Layout — 136-174 MHz

Table 10. AFT05MS031NR1 VHF Broadband Reference Circuit Component Designations and Values — 136-174 MHz

| Part | Description | Part Number | Manufacturer |
|----------------|-----------------------------------|--------------------|-----------------|
| B1 | Low Current Ferrite Bead | 2508051107Y0 | Fair-Rite |
| B2 | High Current Ferrite Bead | 2518065007Y6 | Fair-Rite |
| C1 | 68 pF Chip Capacitor | ATC600F680JT250XT | ATC |
| C2 | 47 pF Chip Capacitor | ATC600F470BT250XT | ATC |
| C3, C4, C6, C7 | 100 pF Chip Capacitors | ATC600F101JT250XT | ATC |
| C5 | 20 pF Chip Capacitor | ATC600F200JT250XT | ATC |
| C8, C9 | 56 pF Chip Capacitors | ATC600F560JT250XT | ATC |
| C10 | 27 pF Chip Capacitor | ATC600F270JT250XT | ATC |
| C11 | 0.1 μ F Chip Capacitor | GRM21BR71H104KA01B | Murata |
| C12 | 1 μ F Chip Capacitor | GRM21BR71H105KA12L | Murata |
| C13, C14, C15 | 240 pF Chip Capacitors | ATC600F241JT250XT | ATC |
| C16, C17 | 10 μ F Chip Capacitors | GRM31CR61H106KA12L | Murata |
| J1 | 3 Pin Connector | AMP-9-146305-0 | TE Connectivity |
| L1 | 19 nH Inductor | 0806SQ-19NGLC | Coilcraft |
| L2 | 6.9 nH Inductor | 0807SQ-6N9GLC | Coilcraft |
| L3 | 27 nH Inductor | 0908SQ-27NGLC | Coilcraft |
| L4 | 6 nH Inductor | 0806SQ-6N0GLC | Coilcraft |
| L5 | 14 nH Inductor | 0807SQ-14NGLC | Coilcraft |
| L6 | 10 nH Inductor | 0807SQ-10NGLC | Coilcraft |
| Q1 | RF Power LDMOS Transistor | AFT05MS031NR1 | Freescale |
| R1 | 62 Ω , 1/4 W Chip Resistor | RG2012N-620-BT1 | Susumu |
| R2 | 0 Ω , 1/4 W Chip Resistor | CWCR08050000Z0EA | Vishay |
| PCB | 0.020", $\epsilon_r = 4.9$ | S1000-2 | Shengyi |

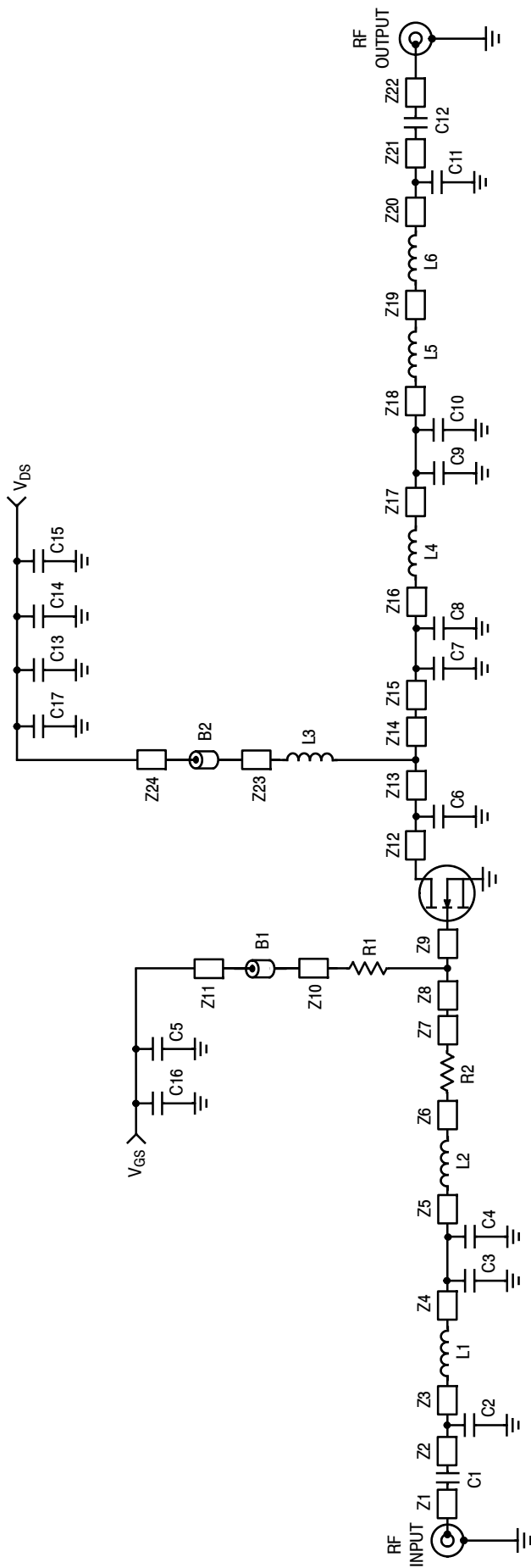


Figure 11. AFT05MS031NR1 VHF Broadband Reference Circuit Schematic — 136-174 MHz

Table 11. AFT05MS031NR1 VHF Broadband Reference Circuit Microstrips — 136-174 MHz

| Microstrip | Description | Microstrip | Description |
|------------|----------------------------|------------|----------------------------|
| Z1 | 0.034" x 0.060" Microstrip | Z9 | 0.240" x 0.170" Microstrip |
| Z2 | 0.034" x 0.120" Microstrip | Z10 | 0.034" x 0.130" Microstrip |
| Z3 | 0.034" x 0.057" Microstrip | Z11 | 0.034" x 0.080" Microstrip |
| Z4 | 0.034" x 0.120" Microstrip | Z12 | 0.240" x 0.155" Microstrip |
| Z5 | 0.034" x 0.075" Microstrip | Z13 | 0.240" x 0.115" Microstrip |
| Z6 | 0.034" x 0.431" Microstrip | Z14 | 0.240" x 0.050" Microstrip |
| Z7 | 0.034" x 0.309" Microstrip | Z15 | 0.034" x 0.065" Microstrip |
| Z8 | 0.240" x 0.020" Microstrip | Z16 | 0.034" x 0.140" Microstrip |
| Z17 | 0.034" x 0.230" Microstrip | Z21 | 0.034" x 0.150" Microstrip |
| Z18 | 0.034" x 0.200" Microstrip | Z22 | 0.034" x 0.060" Microstrip |
| Z19 | 0.034" x 0.190" Microstrip | Z23 | 0.034" x 0.130" Microstrip |
| Z20 | 0.034" x 0.050" Microstrip | Z24 | 0.034" x 0.080" Microstrip |

TYPICAL CHARACTERISTICS — 136-174 MHz VHF BROADBAND REFERENCE CIRCUIT

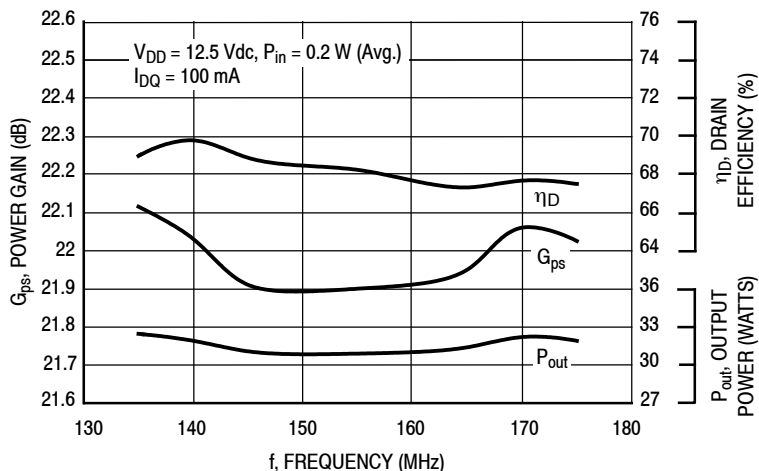


Figure 12. Power Gain, Drain Efficiency and Output Power versus Frequency at a Constant Input Power — 12.5 V

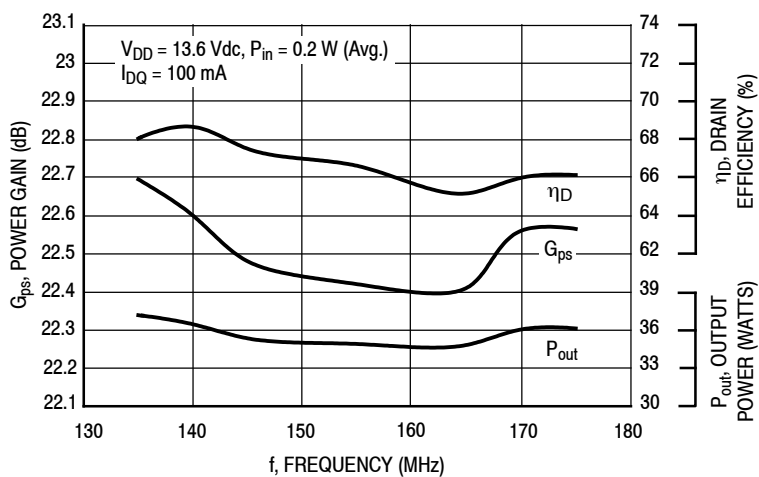
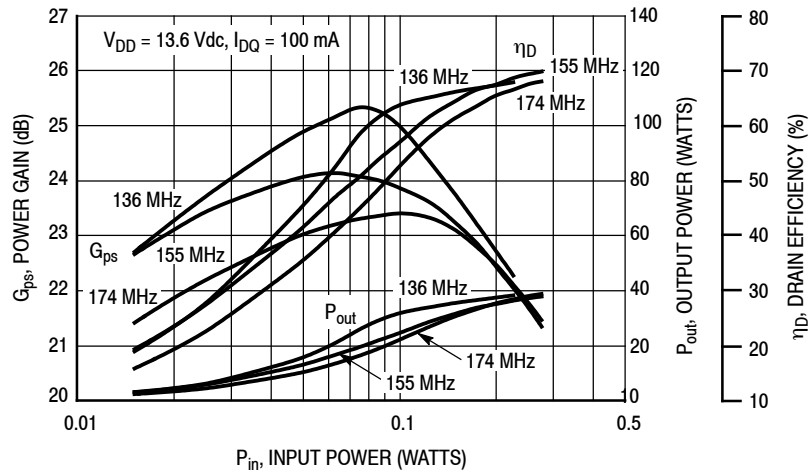
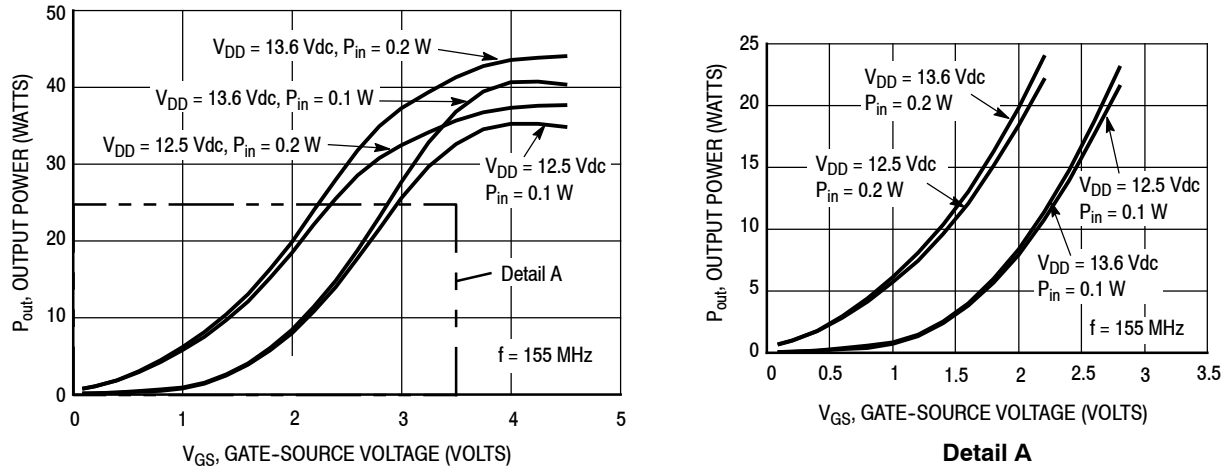
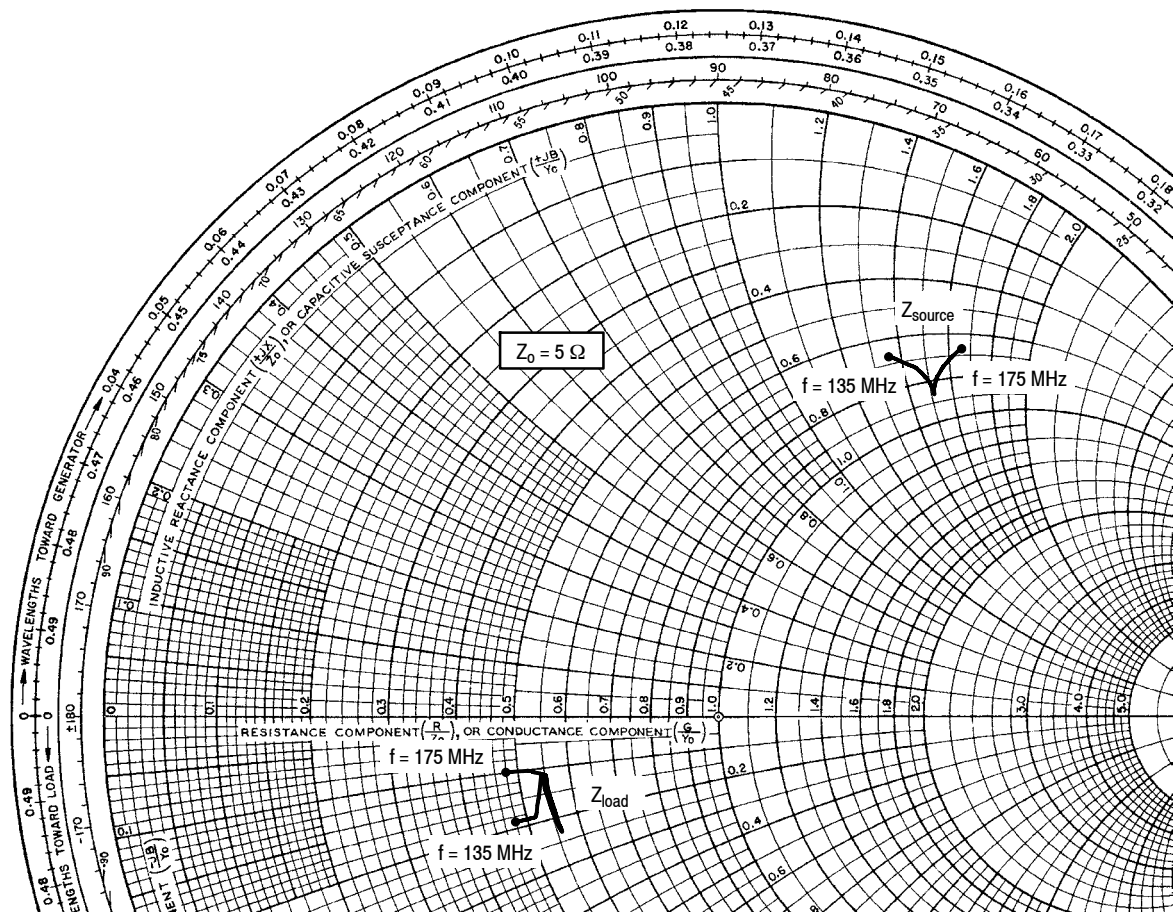


Figure 13. Power Gain, Drain Efficiency and Output Power versus Frequency at a Constant Input Power — 13.6 V

TYPICAL CHARACTERISTICS — 136-174 MHz VHF BROADBAND REFERENCE CIRCUIT



136-174 MHz VHF BROADBAND REFERENCE CIRCUIT



$V_{DD} = 13.6 \text{ Vdc}$, $I_{DQ} = 100 \text{ mA}$, $P_{out} = 31 \text{ W Avg.}$

| f MHz | $Z_{source} \Omega$ | $Z_{load} \Omega$ |
|-------|---------------------|-------------------|
| 135 | $3.33 + j6.92$ | $2.42 - j0.95$ |
| 140 | $3.66 + j7.23$ | $2.59 - j0.96$ |
| 145 | $3.97 + j7.44$ | $2.71 - j1.03$ |
| 150 | $4.21 + j7.53$ | $2.78 - j1.13$ |
| 155 | $4.31 + j7.54$ | $2.77 - j1.23$ |
| 160 | $4.21 + j7.54$ | $2.71 - j1.31$ |
| 165 | $3.94 + j7.65$ | $2.61 - j1.34$ |
| 170 | $3.58 + j7.94$ | $2.50 - j1.32$ |
| 175 | $3.24 + j8.42$ | $2.41 - j1.24$ |

Z_{source} = Test circuit impedance as measured from gate to ground.

Z_{load} = Test circuit impedance as measured from drain to ground.

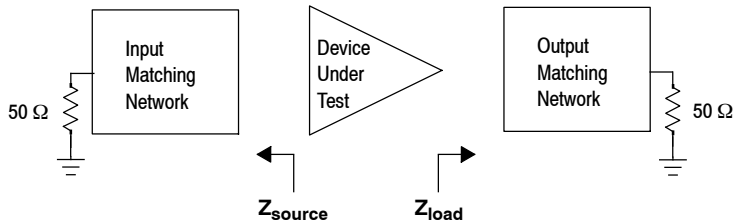


Figure 16. VHF Broadband Series Equivalent Source and Load Impedance — 136-174 MHz

380-450 MHz UHF BROADBAND REFERENCE CIRCUIT

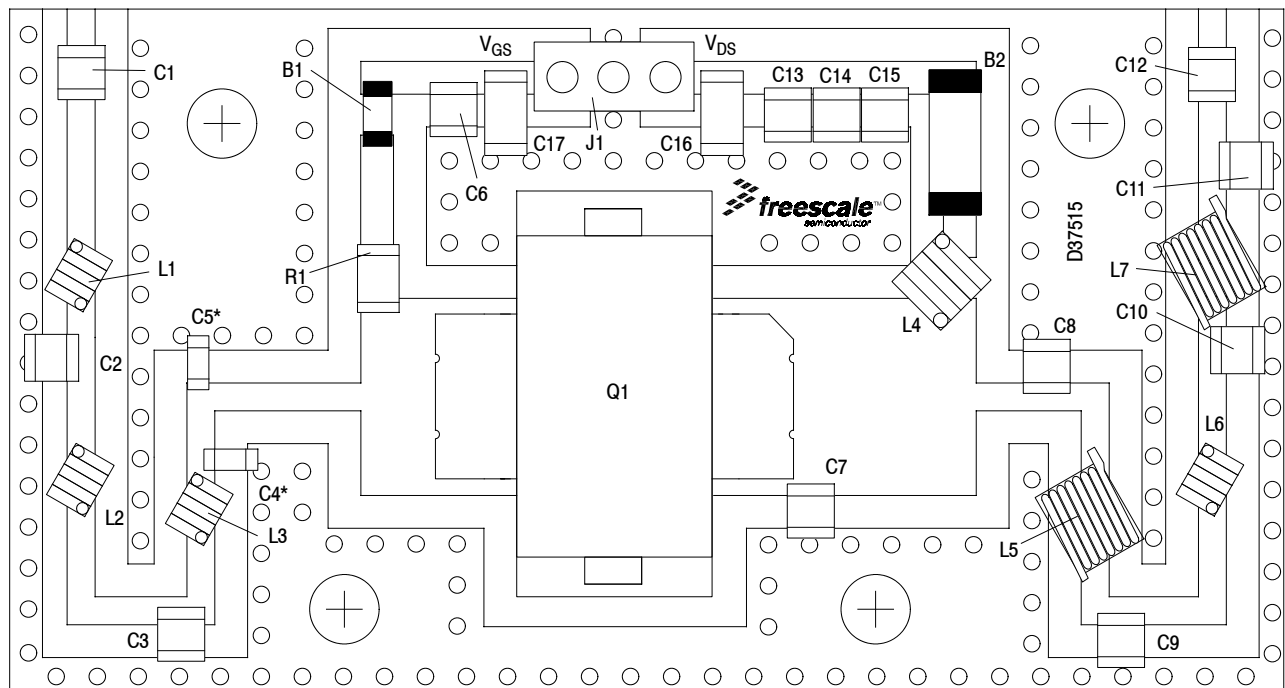
Table 12. 380-450 MHz UHF Broadband Performance (In Freescale Reference Circuit, 50 ohm system)
 $V_{DD} = 13.6$ Volts, $I_{DQ} = 100$ mA, $T_A = 25^\circ\text{C}$, CW

| Frequency (MHz) | G_{ps} (dB) | η_D (%) | P1dB (W) |
|-----------------|---------------|--------------|----------|
| 380 | 18.7 | 64.1 | 31 |
| 420 | 18.6 | 67.0 | 31 |
| 450 | 18.3 | 68.1 | 31 |

Table 13. Load Mismatch/Ruggedness (In Freescale Reference Circuit)

| Frequency (MHz) | Signal Type | VSWR | P_{in} (W) | Test Voltage, V_{DD} | Result |
|-----------------|-------------|---------------------------|-------------------------|------------------------|-----------------------|
| 420 | CW | >65:1 at all Phase Angles | 1.6 (3 dB Overdrive) | 17 | No Device Degradation |

380-450 MHz UHF BROADBAND REFERENCE CIRCUIT



* C4 and C5 are mounted vertically.

Figure 17. AFT05MS031NR1 UHF Broadband Reference Circuit Component Layout — 380-450 MHz

Table 14. AFT05MS031NR1 UHF Broadband Reference Circuit Component Designations and Values — 380-450 MHz

| Part | Description | Part Number | Manufacturer |
|----------------|-----------------------------------|--------------------|-----------------|
| B1 | Low Current Ferrite Bead | 2508051107Y0 | Fair-Rite |
| B2 | High Current Ferrite Bead | 2518065007Y6 | Fair-Rite |
| C1, C5 | 56 pF Chip Capacitors | ATC600F560JT250XT | ATC |
| C2 | 3.9 pF Chip Capacitor | ATC600F3R9BT250XT | ATC |
| C3 | 18 pF Chip Capacitor | ATC600F180JT250XT | ATC |
| C4 | 47 pF Chip Capacitor | ATC600F470JT250XT | ATC |
| C6, C12, C15 | 240 pF Chip Capacitors | ATC600F241JT250XT | ATC |
| C7 | 24 pF Chip Capacitor | ATC600F240JT250XT | ATC |
| C8 | 68 pF Chip Capacitor | ATC600F680JT250XT | ATC |
| C9 | 27 pF Chip Capacitor | ATC600F270JT250XT | ATC |
| C10 | 8.2 pF Chip Capacitor | ATC600F8R2BT250XT | ATC |
| C11 | 3.0 pF Chip Capacitor | ATC600F3R0BT250XT | ATC |
| C13 | 0.1 μ F Chip Capacitor | GRM21BR71H104KA01B | Murata |
| C14 | 1 μ F Chip Capacitor | GRM21BR71H105KA12L | Murata |
| C16, C17 | 10 μ F Chip Capacitors | GRM31CR61H106KA12L | Murata |
| J1 | 3 Pin Connector | AMP-9-146305-0 | TE Connectivity |
| L1, L2, L3, L6 | 5.5 nH Inductors | 0806SQ-5N5GLC | Coilcraft |
| L4 | 17 nH Inductor | 0908SQ-17NGLC | Coilcraft |
| L5 | 1.65 nH Inductor | 0906-2KLC | Coilcraft |
| L7 | 2.55 nH Inductor | 0906-3JLC | Coilcraft |
| Q1 | RF Power LDMOS Transistor | AFT05MS031NR1 | Freescale |
| R1 | 62 Ω , 1/4 W Chip Resistor | RG2012N-620-BT1 | Susumu |
| PCB | 0.020", $\epsilon_r = 4.9$ | S1000-2 | Shengyi |

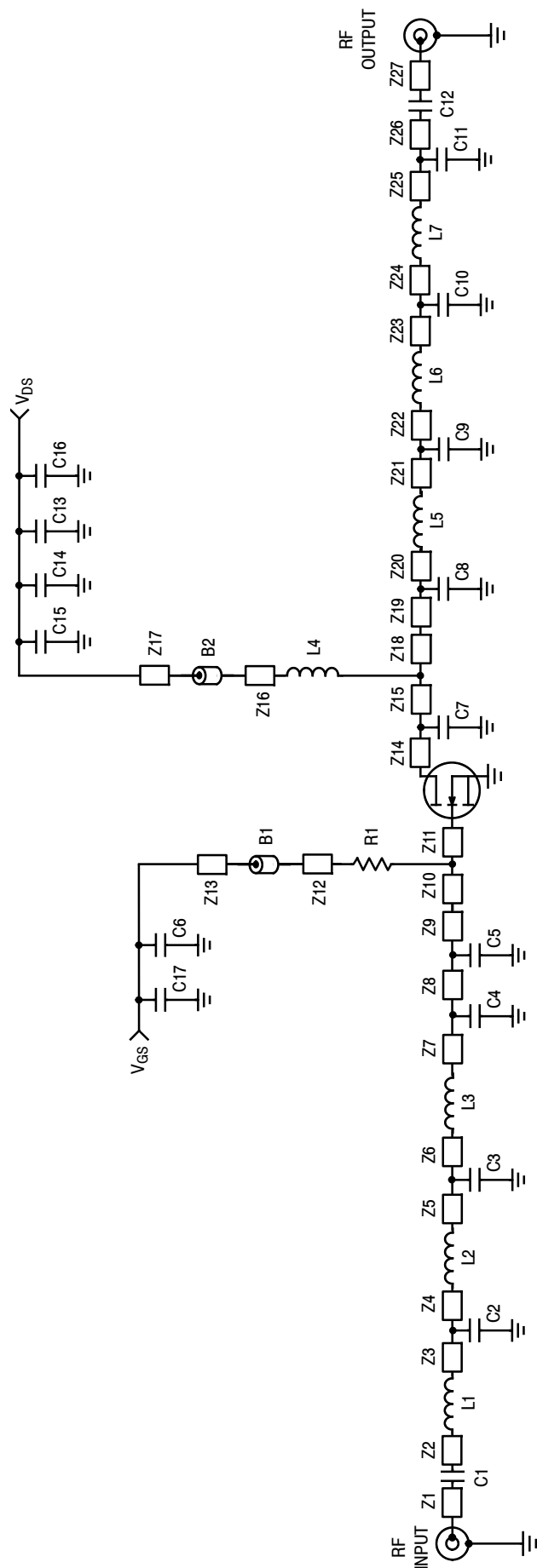


Figure 18. AFT05MS031NR1 UHF Broadband Reference Circuit Schematic — 380–450 MHz

Table 15. AFT05MS031NR1 UHF Broadband Reference Circuit Microstrips — 380–450 MHz

| Microstrip | Description | Microstrip | Description | Microstrip | Description |
|------------|----------------------------|------------|----------------------------|------------|----------------------------|
| Z1 | 0.034" x 0.060" Microstrip | Z10 | 0.240" x 0.048" Microstrip | Z19 | 0.034" x 0.057" Microstrip |
| Z2 | 0.034" x 0.200" Microstrip | Z11 | 0.240" x 0.142" Microstrip | Z20* | 0.034" x 0.201" Microstrip |
| Z3 | 0.034" x 0.056" Microstrip | Z12 | 0.034" x 0.149" Microstrip | Z21* | 0.034" x 0.110" Microstrip |
| Z4 | 0.034" x 0.154" Microstrip | Z13* | 0.034" x 0.085" Microstrip | Z22* | 0.034" x 0.361" Microstrip |
| Z5* | 0.034" x 0.237" Microstrip | Z14 | 0.240" x 0.090" Microstrip | Z23 | 0.034" x 0.112" Microstrip |
| Z6* | 0.034" x 0.234" Microstrip | Z15 | 0.240" x 0.186" Microstrip | Z24 | 0.034" x 0.083" Microstrip |
| Z7 | 0.034" x 0.010" Microstrip | Z16 | 0.034" x 0.149" Microstrip | Z25 | 0.034" x 0.073" Microstrip |
| Z8 | 0.034" x 0.083" Microstrip | Z17* | 0.034" x 0.085" Microstrip | Z26 | 0.034" x 0.077" Microstrip |
| Z9 | 0.034" x 0.178" Microstrip | Z18 | 0.240" x 0.044" Microstrip | Z27 | 0.034" x 0.060" Microstrip |

* Line length includes microstrip bends

TYPICAL CHARACTERISTICS — 380-450 MHz UHF BROADBAND REFERENCE CIRCUIT

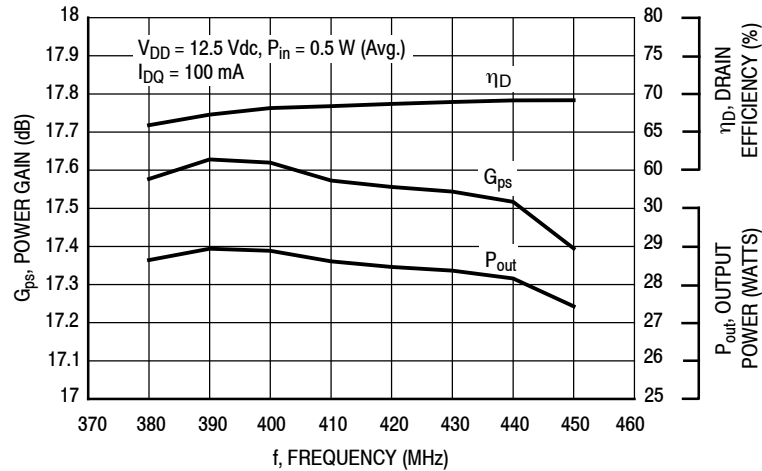


Figure 19. Power Gain, Drain Efficiency and Output Power versus Frequency at a Constant Input Power — 12.5 V

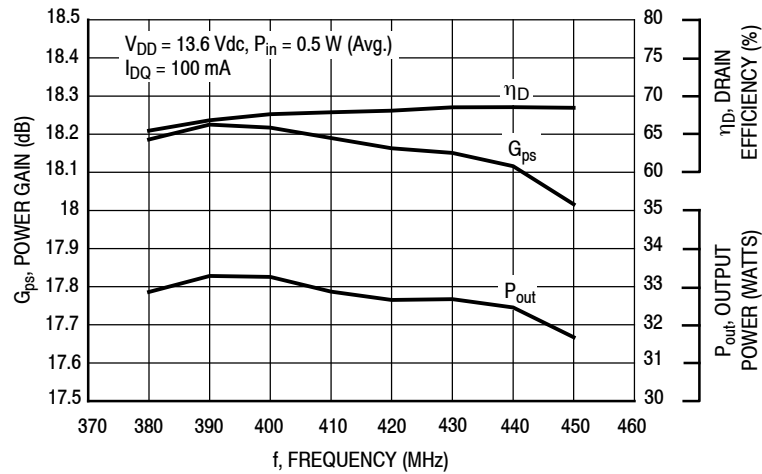


Figure 20. Power Gain, Drain Efficiency and Output Power versus Frequency at a Constant Input Power — 13.6 V

TYPICAL CHARACTERISTICS — 380-450 MHz UHF BROADBAND REFERENCE CIRCUIT

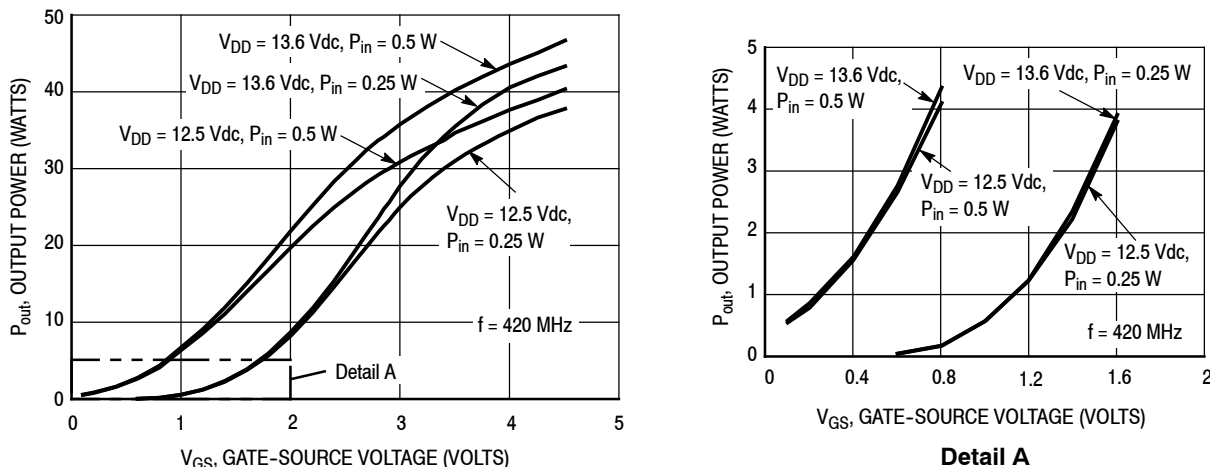


Figure 21. Output Power versus Gate-Source Voltage

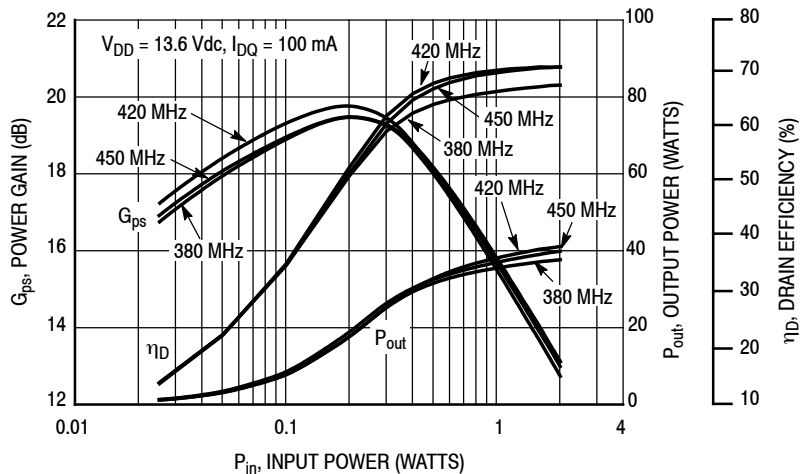
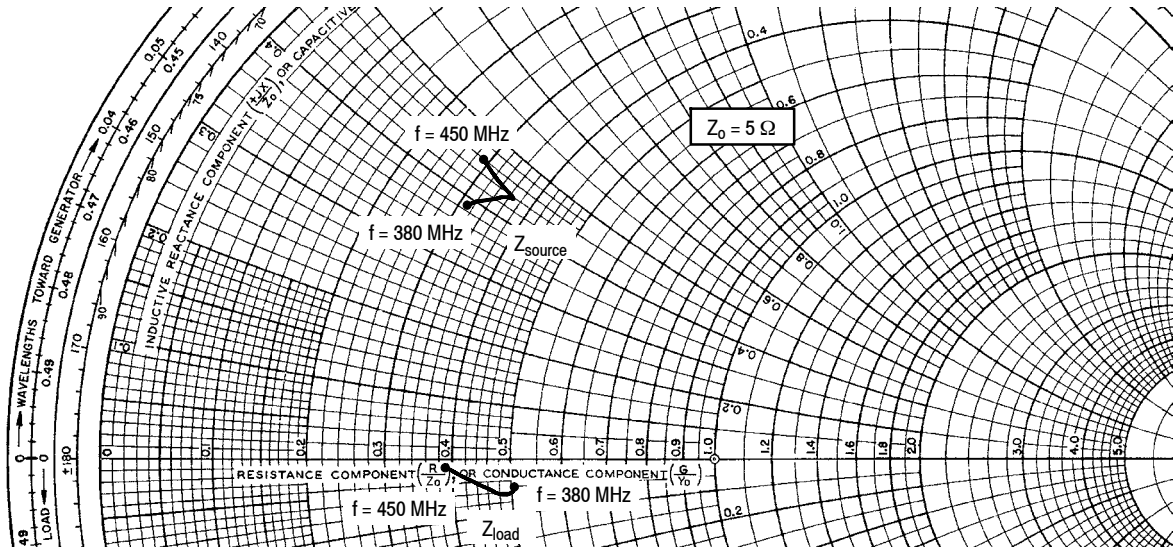


Figure 22. Power Gain, Output Power and Drain Efficiency versus Input Power and Frequency

380-450 MHz UHF BROADBAND REFERENCE CIRCUIT



$V_{DD} = 13.6 \text{ Vdc}$, $I_{DQ} = 100 \text{ mA}$, $P_{out} = 31 \text{ W Avg.}$

| f MHz | Z_{source} Ω | Z_{load} Ω |
|----------|--------------------------|------------------------|
| 380 | $1.57 + j1.94$ | $2.53 - j0.27$ |
| 390 | $1.66 + j2.07$ | $2.53 - j0.26$ |
| 400 | $1.74 + j2.16$ | $2.56 - j0.27$ |
| 410 | $1.79 + j2.20$ | $2.49 - j0.29$ |
| 420 | $1.79 + j2.21$ | $2.38 - j0.28$ |
| 430 | $1.74 + j2.21$ | $2.26 - j0.24$ |
| 440 | $1.62 + j2.23$ | $2.11 - j0.16$ |
| 450 | $1.45 + j2.29$ | $1.95 - j0.05$ |

Z_{source} = Test circuit impedance as measured from gate to ground.

Z_{load} = Test circuit impedance as measured from drain to ground.

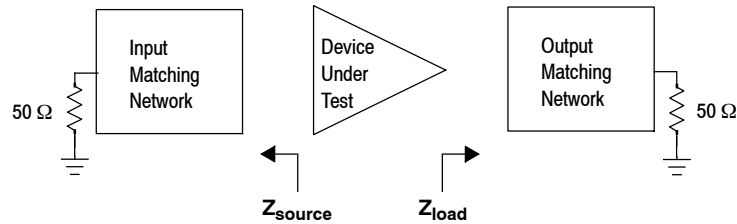


Figure 23. UHF Broadband Series Equivalent Source and Load Impedance — 380-450 MHz

450-520 MHz UHF BROADBAND REFERENCE CIRCUIT

Table 16. 450-520 MHz UHF Broadband Performance (In Freescale Reference Circuit, 50 ohm system)
 $V_{DD} = 13.6$ Volts, $I_{DQ} = 100$ mA, $T_A = 25^\circ\text{C}$, CW

| Frequency (MHz) | G_{ps} (dB) | η_D (%) | P1dB (W) |
|-----------------|---------------|--------------|----------|
| 450 | 17.7 | 62.0 | 31 |
| 490 | 18.7 | 63.8 | 31 |
| 520 | 17.9 | 67.0 | 31 |

Table 17. Load Mismatch/Ruggedness (In Freescale Reference Circuit)

| Frequency (MHz) | Signal Type | VSWR | P_{in} (W) | Test Voltage, V_{DD} | Result |
|-----------------|-------------|---------------------------|-------------------------|------------------------|-----------------------|
| 490 | CW | >65:1 at all Phase Angles | 2.0 (3 dB Overdrive) | 17 | No Device Degradation |

450-520 MHz UHF BROADBAND REFERENCE CIRCUIT

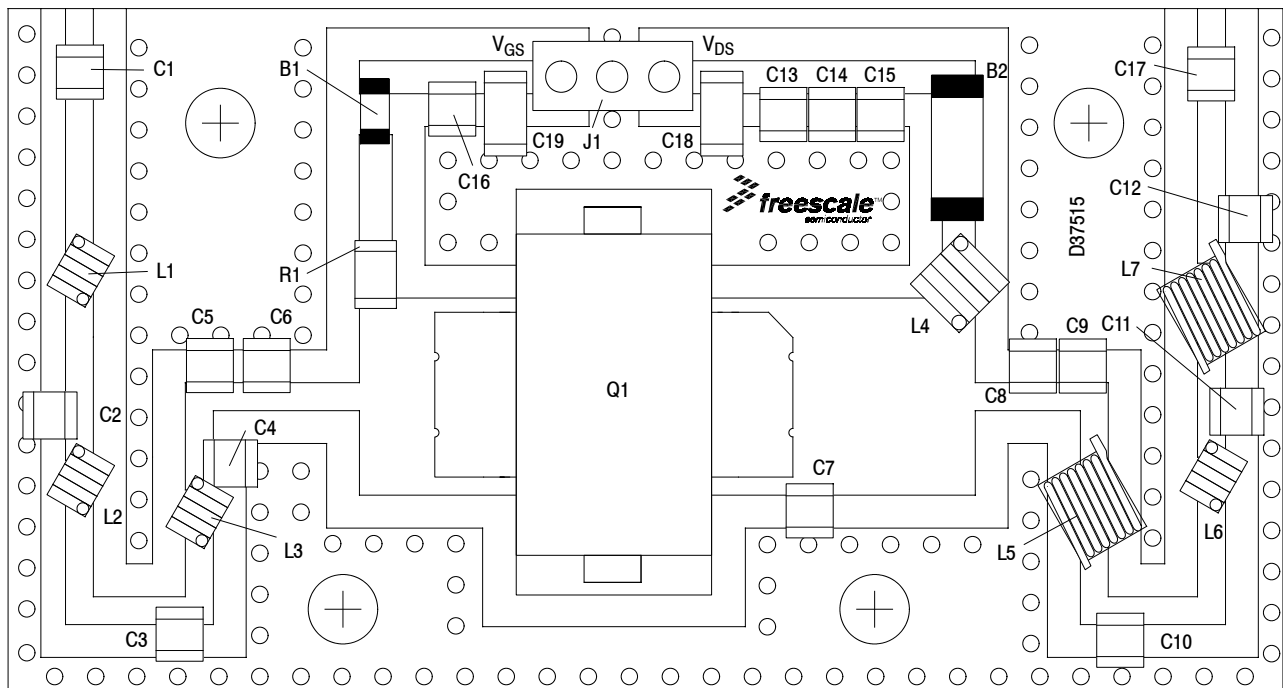


Figure 24. AFT05MS031NR1 UHF Broadband Reference Circuit Component Layout — 450-520 MHz

Table 18. AFT05MS031NR1 UHF Broadband Reference Circuit Component Designations and Values — 450-520 MHz

| Part | Description | Part Number | Manufacturer |
|---------------|------------------------------|--------------------|-----------------|
| B1 | Low Current Ferrite Bead | 2508051107Y0 | Fair-Rite |
| B2 | High Current Ferrite Bead | 2518065007Y6 | Fair-Rite |
| C1 | 56 pF Chip Capacitor | ATC600F560JT250XT | ATC |
| C2 | 2.7 pF Chip Capacitor | ATC600F2R7BT250XT | ATC |
| C3 | 12 pF Chip Capacitor | ATC600F120JT250XT | ATC |
| C4, C9 | 27 pF Chip Capacitors | ATC600F270JT250XT | ATC |
| C5, C8 | 33 pF Chip Capacitors | ATC600F330JT250XT | ATC |
| C6 | 39 pF Chip Capacitor | ATC600F390JT250XT | ATC |
| C7, C10 | 18 pF Chip Capacitors | ATC600F180JT250XT | ATC |
| C11 | 8.2 pF Chip Capacitor | ATC600F8R2BT250XT | ATC |
| C12 | 1.8 pF Chip Capacitor | ATC600F1R8BT250XT | ATC |
| C13 | 0.1 μF Chip Capacitor | GRM21BR71H104KA01B | Murata |
| C14 | 1 μF Chip Capacitor | GRM21BR71H105KA12L | Murata |
| C15, C16, C17 | 240 pF Chip Capacitors | ATC600F241JT250XT | ATC |
| C18, C19 | 10 μF Chip Capacitors | GRM31CR61H106KA12L | Murata |
| J1 | 3 Pin Connector | AMP-9-146305-0 | TE Connectivity |
| L1, L3 | 6.0 nH Inductors | 0806SQ-6N0GLC | Coilcraft |
| L2, L6 | 5.5 nH Inductors | 0806SQ5N5GLC | Coilcraft |
| L4 | 17 nH Inductor | 0908SQ-17NGLC | Coilcraft |
| L5, L7 | 1.65 nH Inductors | 0906-2KLC | Coilcraft |
| Q1 | RF Power LDMOS Transistor | AFT05MS031NR1 | Freescale |
| R1 | 62 Ω, 1/4 W Chip Resistor | RG2012N-620-BT1 | Susumu |
| PCB | 0.020", ε _r = 4.9 | S1000-2 | Shengyi |

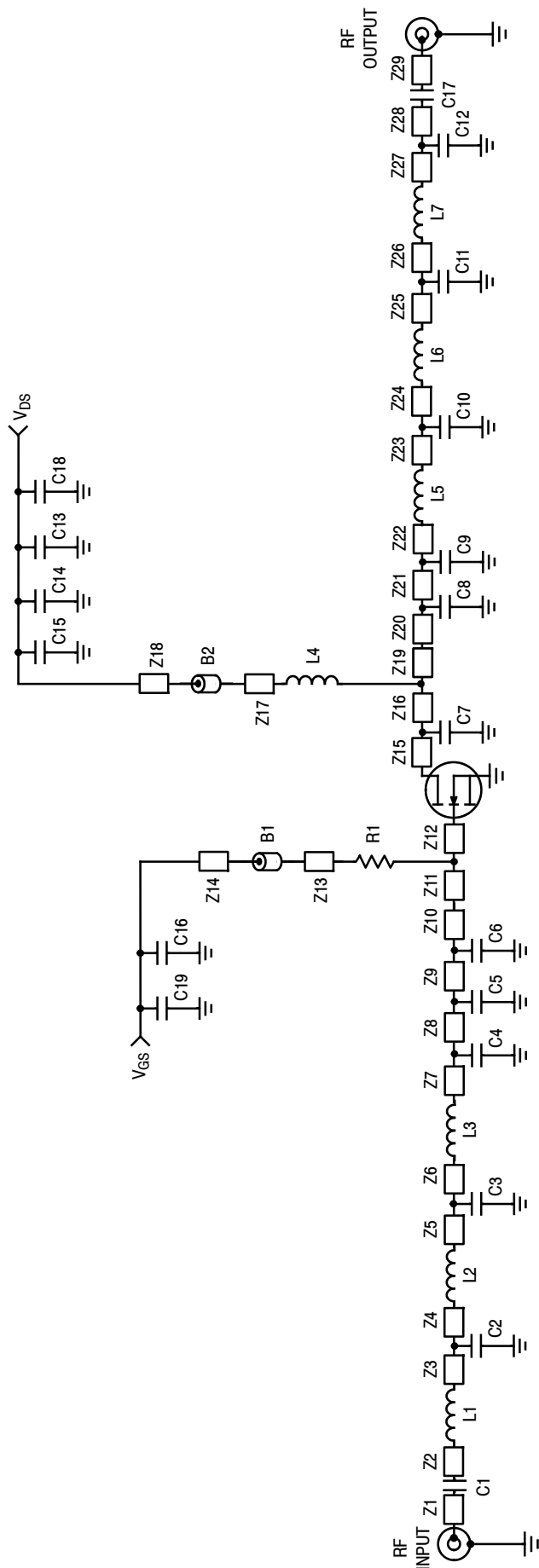


Figure 25. AFT05MS031NR1 UHF Broadband Reference Circuit Schematic — 450-520 MHz

Table 19. AFT05MS031NR1 UHF Broadband Reference Circuit Microstrips — 450-520 MHz

| Microstrip | Description | Microstrip | Description |
|------------|----------------------------|------------|-----------------------------|
| Z1 | 0.034" x 0.060" Microstrip | Z21 | 0.034" x 0.010" Microstrip |
| Z2 | 0.034" x 0.200" Microstrip | Z22 | 0.034" x 0.176" Microstrip |
| Z3 | 0.034" x 0.128" Microstrip | Z23* | 0.034" x 0.118" Microstrip* |
| Z4 | 0.034" x 0.054" Microstrip | Z24* | 0.034" x 0.295" Microstrip* |
| Z5* | 0.034" x 0.202" Microstrip | Z25 | 0.034" x 0.018" Microstrip |
| Z6* | 0.034" x 0.160" Microstrip | Z26 | 0.034" x 0.177" Microstrip |
| Z7 | 0.034" x 0.010" Microstrip | Z27 | 0.034" x 0.022" Microstrip |
| Z8 | 0.034" x 0.115" Microstrip | Z28 | 0.034" x 0.188" Microstrip |
| Z9 | 0.034" x 0.060" Microstrip | Z29 | 0.034" x 0.060" Microstrip |
| Z10 | 0.034" x 0.150" Microstrip | | |

* Line length includes microstrip bends

TYPICAL CHARACTERISTICS — 450-520 MHz UHF BROADBAND REFERENCE CIRCUIT

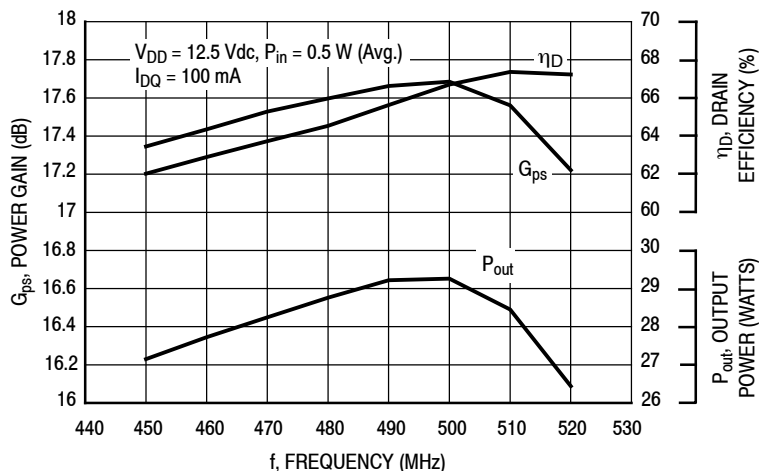


Figure 26. Power Gain, Drain Efficiency and Output Power versus Frequency at a Constant Input Power — 12.5 V

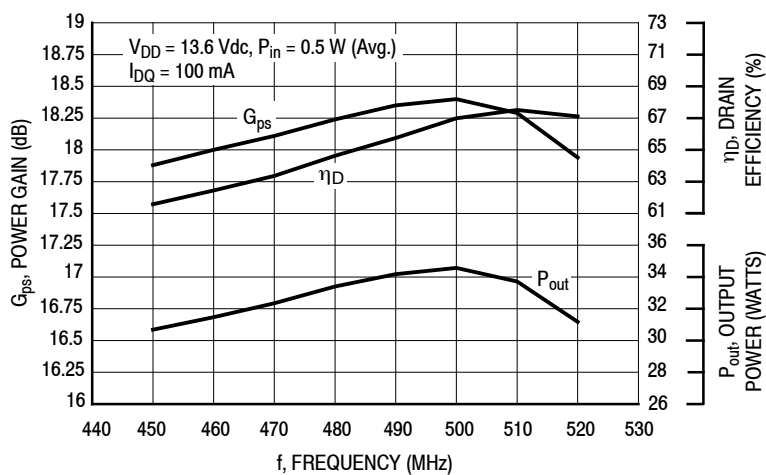


Figure 27. Power Gain, Drain Efficiency and Output Power versus Frequency at a Constant Input Power — 13.6 V

TYPICAL CHARACTERISTICS — 450-520 MHz UHF BROADBAND REFERENCE CIRCUIT

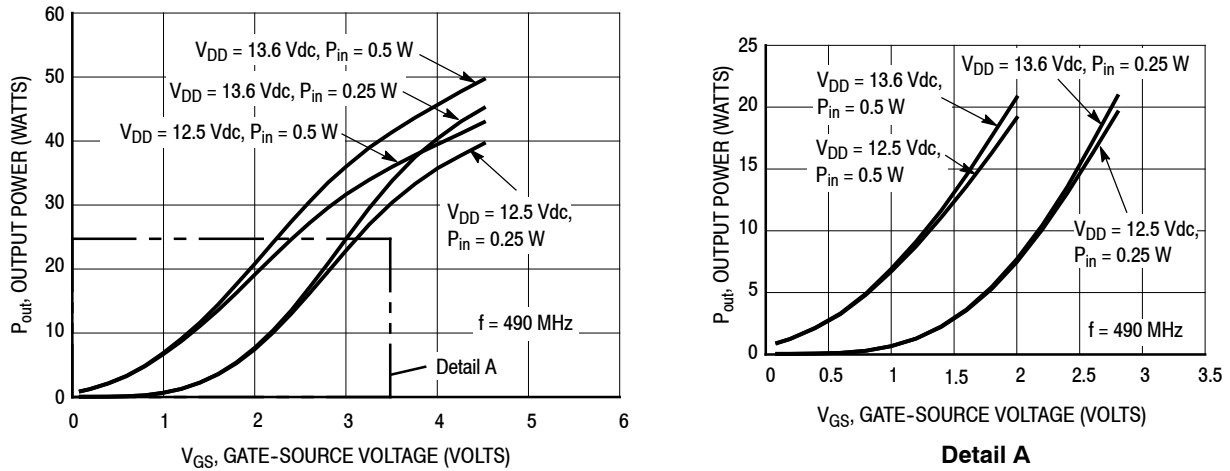


Figure 28. Output Power versus Gate-Source Voltage

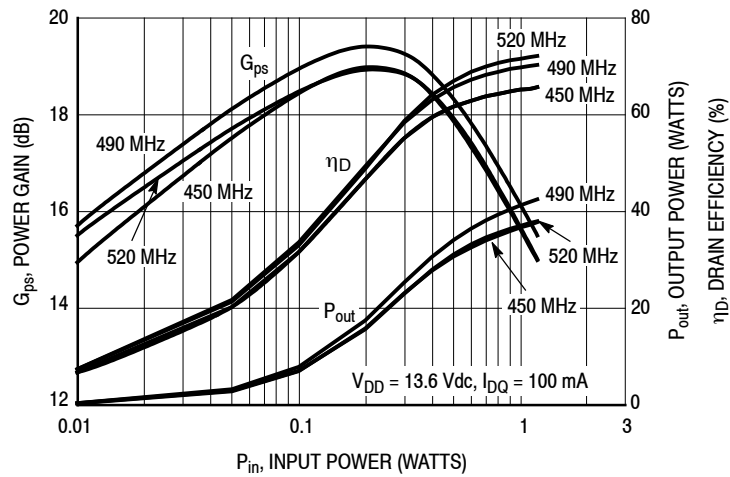
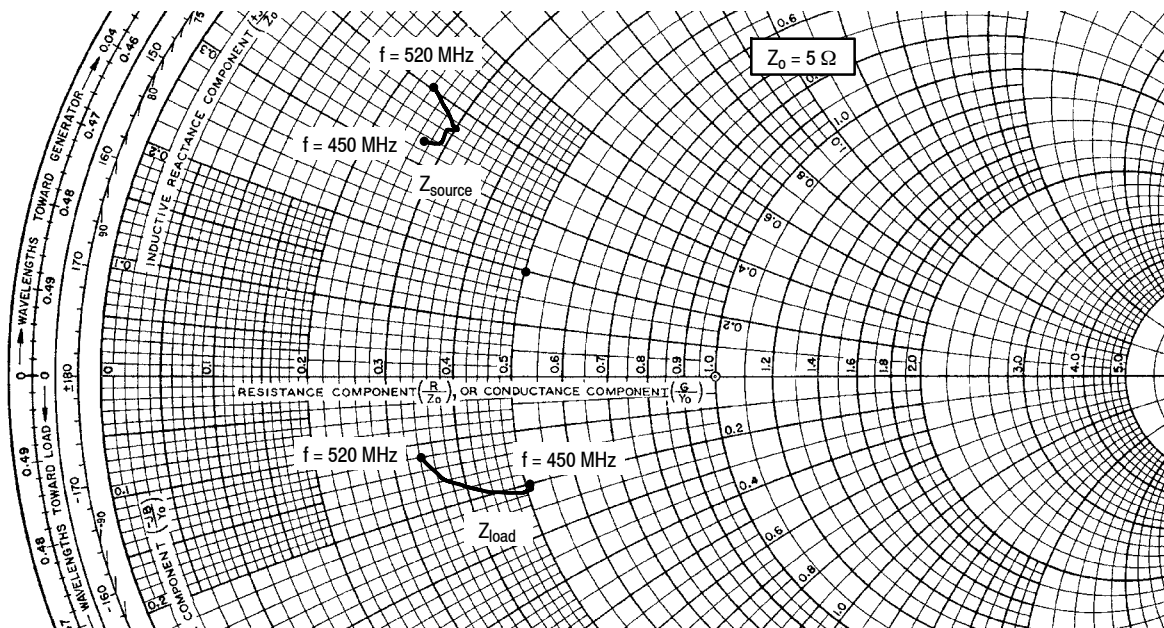


Figure 29. Power Gain, Output Power and Drain Efficiency versus Input Power and Frequency

450-520 MHz UHF BROADBAND REFERENCE CIRCUIT



$V_{DD} = 13.6 \text{ Vdc}$, $I_{DQ} = 100 \text{ mA}$, $P_{out} = 31 \text{ W Avg.}$

| f MHz | Z_{source} Ω | Z_{load} Ω |
|----------|--------------------------|------------------------|
| 450 | $1.37 + j1.64$ | $2.57 - j1.01$ |
| 460 | $1.43 + j1.72$ | $2.49 - j1.03$ |
| 470 | $1.47 + j1.79$ | $2.38 - j1.03$ |
| 480 | $1.49 + j1.83$ | $2.26 - j1.01$ |
| 490 | $1.47 + j1.86$ | $2.11 - j0.95$ |
| 500 | $1.41 + j1.89$ | $1.97 - j0.87$ |
| 510 | $1.32 + j1.93$ | $1.82 - j0.76$ |
| 520 | $1.20 + j1.99$ | $1.68 - j0.62$ |

Z_{source} = Test circuit impedance as measured from gate to ground.

Z_{load} = Test circuit impedance as measured from drain to ground.

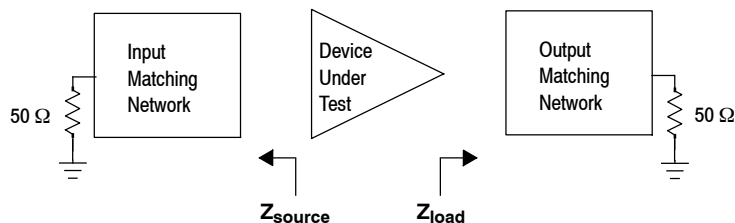
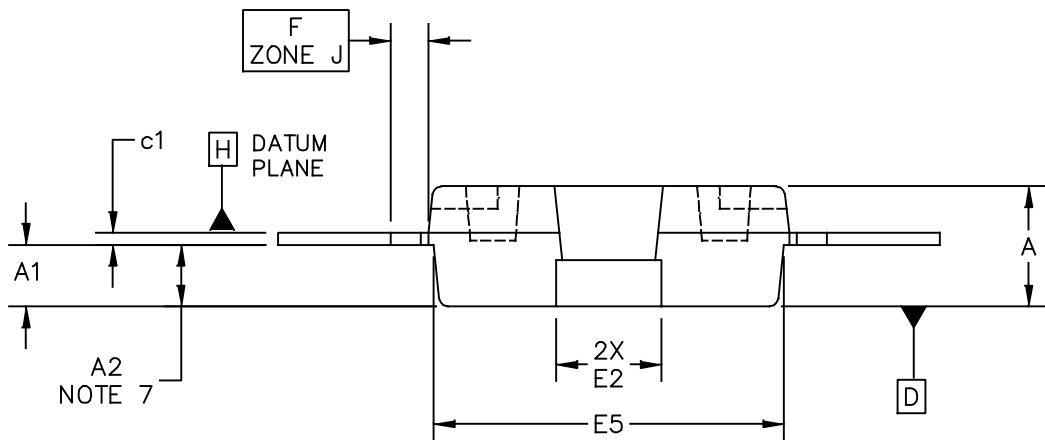
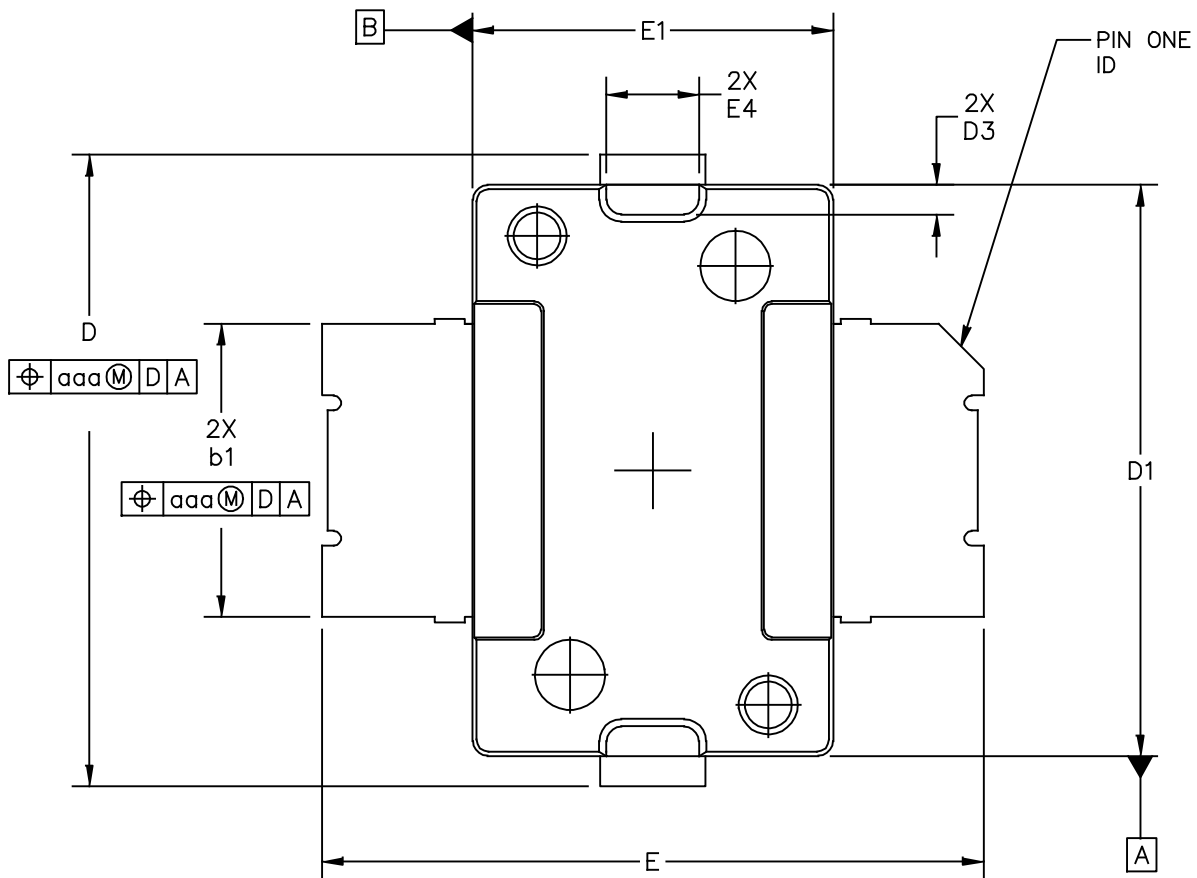
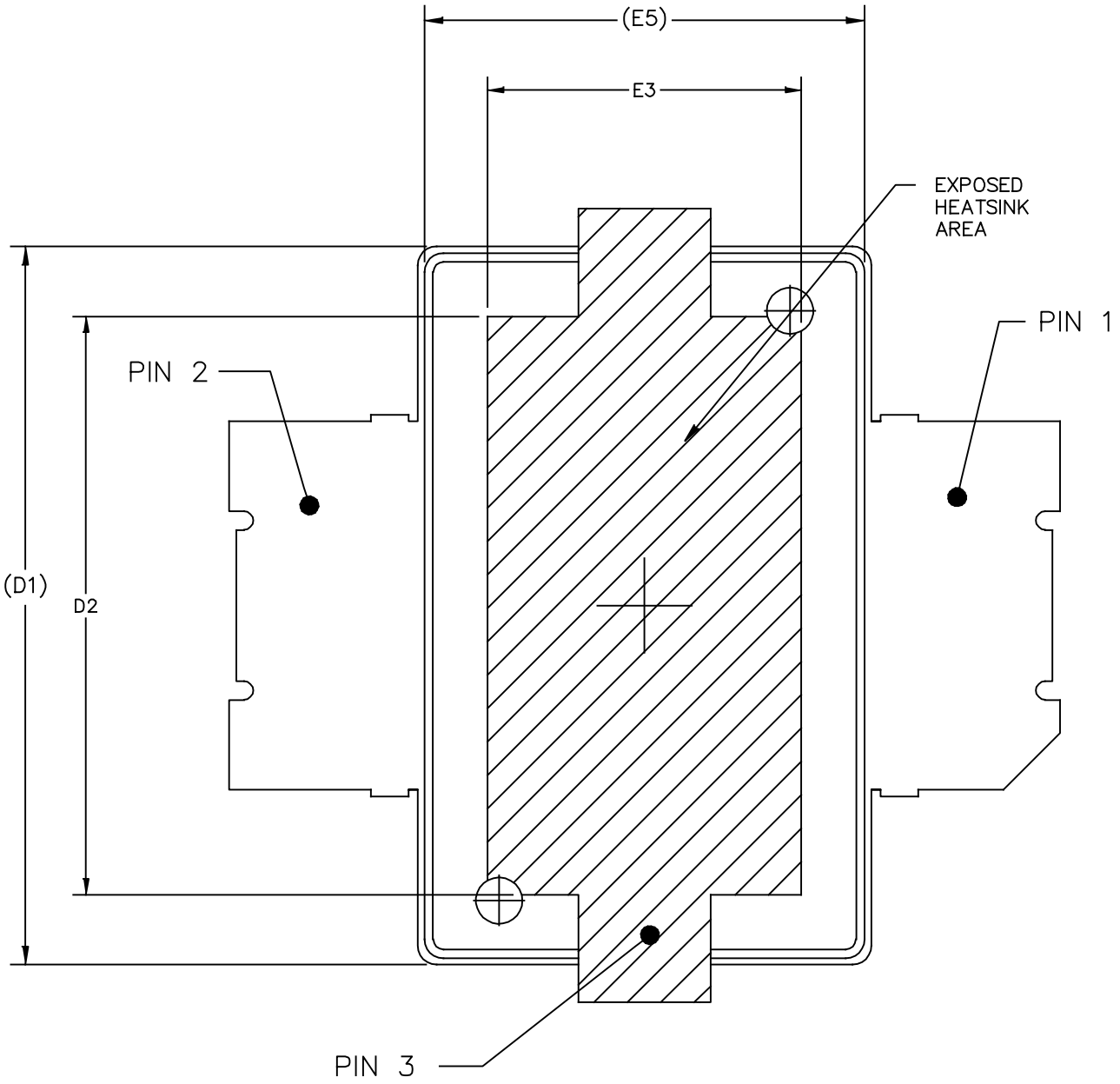


Figure 30. UHF Broadband Series Equivalent Source and Load Impedance — 450-520 MHz

PACKAGE DIMENSIONS



| | | | |
|---|---------------------------|----------------------------|--|
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| | CASE NUMBER: 1265-09 | 29 JUN 2007 | |
| | STANDARD: JEDEC TO-270 AA | | |



BOTTOM VIEW

| | | | |
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| | CASE NUMBER: 1265-09 | 29 JUN 2007 | |
| | STANDARD: JEDEC TO-270 AA | | |

NOTES:

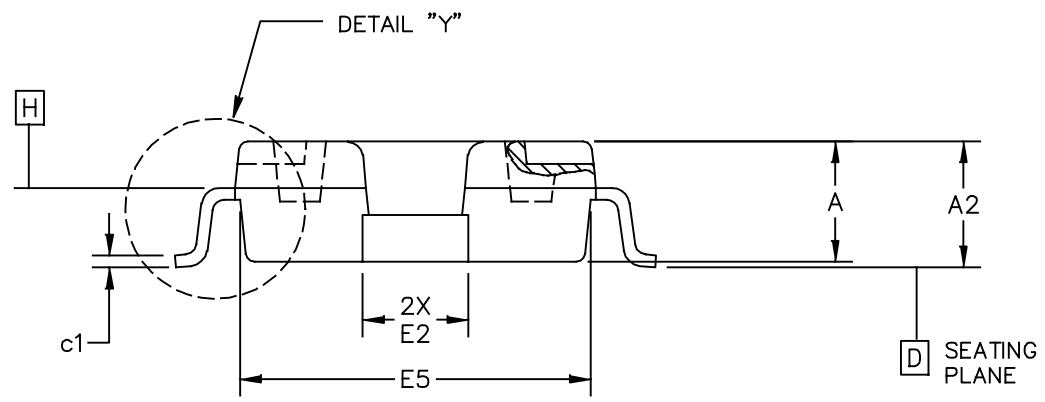
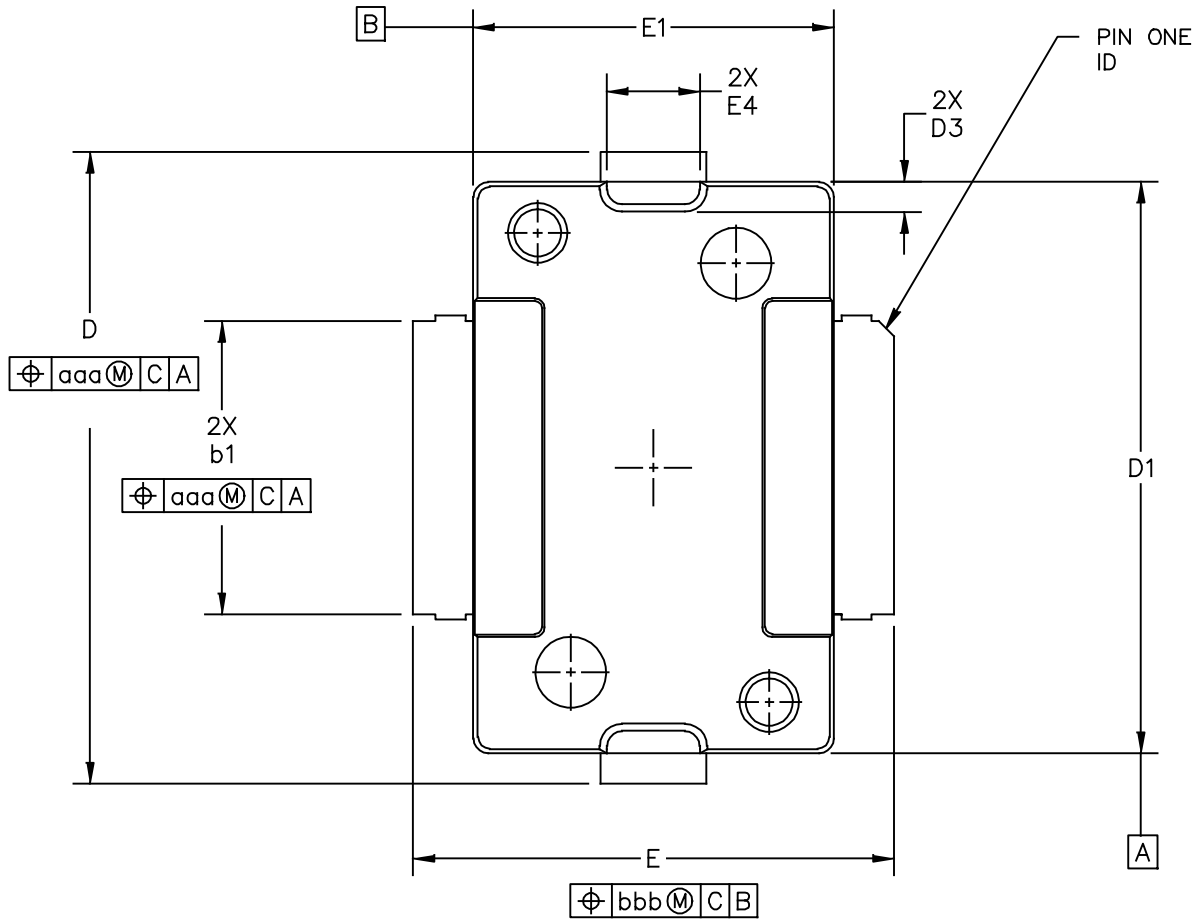
1. CONTROLLING DIMENSION: INCH
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
3. DATUM PLANE -H- IS LOCATED AT TOP OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE TOP OF THE PARTING LINE.
4. DIMENSIONS "D1" AND "E1" DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS .006 PER SIDE. DIMENSIONS "D1 AND "E1" DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE -H-.
5. DIMENSION "b1" DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .005 TOTAL IN EXCESS OF THE "b1" DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. DATUMS -A- AND -B- TO BE DETERMINED AT DATUM PLANE -H-.
7. DIMENSION "A2" APPLIES WITHIN ZONE "J" ONLY.
8. DIMENSIONS "D" AND "E2" DO NOT INCLUDE MOLD PROTRUSION. OVERALL LENGTH INCLUDING MOLD PROTRUSION SHOULD NOT EXCEED 0.430 INCH FOR DIMENSION "D" AND 0.080 INCH FOR DIMENSION "E2". DIMENSIONS "D" AND "E2" DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE -D-.

STYLE 1:

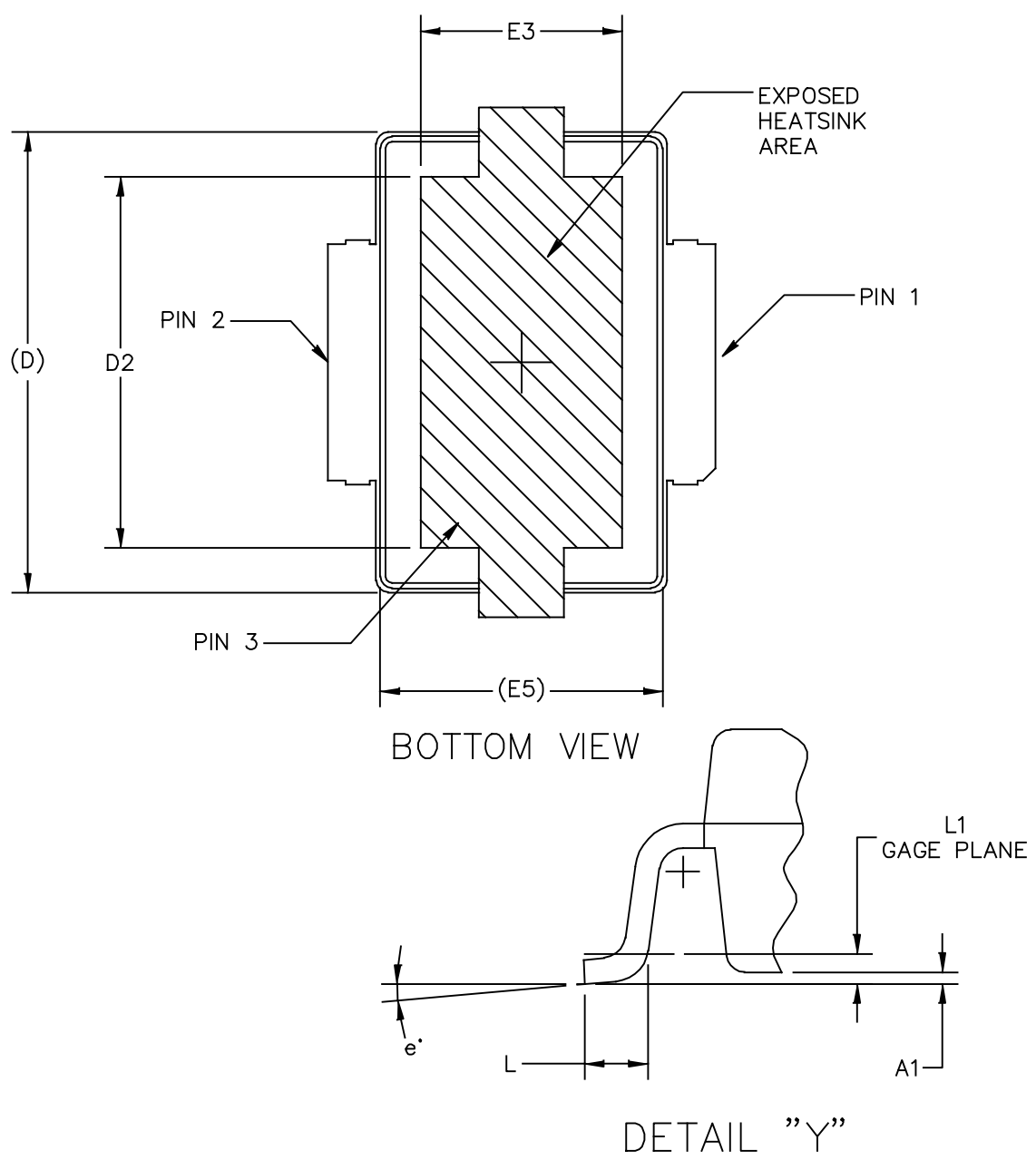
- PIN 1 - DRAIN
- PIN 2 - GATE
- PIN 3 - SOURCE

| DIM | INCH | | MILLIMETER | | DIM | INCH | | MILLIMETER | |
|-----|------|------|------------|-------|-----|----------|------|------------|------|
| | MIN | MAX | MIN | MAX | | MIN | MAX | MIN | MAX |
| A | .078 | .082 | 1.98 | 2.08 | F | .025 BSC | | 0.64 BSC | |
| A1 | .039 | .043 | 0.99 | 1.09 | b1 | .193 | .199 | 4.90 | 5.06 |
| A2 | .040 | .042 | 1.02 | 1.07 | c1 | .007 | .011 | 0.18 | 0.28 |
| D | .416 | .424 | 10.57 | 10.77 | aaa | .004 | | 0.10 | |
| D1 | .378 | .382 | 9.60 | 9.70 | | | | | |
| D2 | .290 | ---- | 7.37 | ---- | | | | | |
| D3 | .016 | .024 | 0.41 | 0.61 | | | | | |
| E | .436 | .444 | 11.07 | 11.28 | | | | | |
| E1 | .238 | .242 | 6.04 | 6.15 | | | | | |
| E2 | .066 | .074 | 1.68 | 1.88 | | | | | |
| E3 | .150 | ---- | 3.81 | ---- | | | | | |
| E4 | .058 | .066 | 1.47 | 1.68 | | | | | |
| E5 | .231 | .235 | 5.87 | 5.97 | | | | | |

| | | | |
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| TITLE: TO-270 GULL WING | | DOCUMENT NO: 98ASA99301D | | REV: C | |
| | | CASE NUMBER: 1265A-03 | | 02 JUL 2007 | |
| | | STANDARD: JEDEC TO-270 BA | | | |



| | | | |
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| TITLE: TO-270 GULL WING | DOCUMENT NO: 98ASA99301D | | REV: C |
| | CASE NUMBER: 1265A-03 | | 02 JUL 2007 |
| | STANDARD: JEDEC TO-270 BA | | |

NOTES:

1. CONTROLLING DIMENSION: INCH
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
3. DATUM PLANE -H- IS LOCATED AT TOP OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE TOP OF THE PARTING LINE.
4. DIMENSIONS "D1" AND "E1" DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS .006 PER SIDE. DIMENSIONS "D1 AND "E1" DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE -H-.
5. DIMENSION b1 DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .005 TOTAL IN EXCESS OF THE b1 DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. DATUMS -A- AND -B- TO BE DETERMINED AT DATUM PLANE -H-.
7. DIMENSIONS "D" AND "E2" DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS .003 PER SIDE. DIMENSIONS "D AND "E2" DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE -D-.

STYLE 1:

- PIN 1 - DRAIN
- PIN 2 - GATE
- PIN 3 - SOURCE

| DIM | INCH | | MILLIMETER | | DIM | INCH | | MILLIMETER | |
|---|------|------|--------------------|-------|---------------------------|----------------------------|------|-------------|------|
| | MIN | MAX | MIN | MAX | | MIN | MAX | MIN | MAX |
| A | .078 | .082 | 1.98 | 2.08 | L | .018 | .024 | 0.46 | 0.61 |
| A1 | .001 | .004 | 0.02 | 0.10 | L1 | .01 BSC | | 0.25 BSC | |
| A2 | .077 | .088 | 1.96 | 2.24 | b1 | .193 | .199 | 4.90 | 5.06 |
| D | .416 | .424 | 10.57 | 10.77 | c1 | .007 | .011 | 0.18 | 0.28 |
| D1 | .378 | .382 | 9.60 | 9.70 | e | 2' | 8' | 2' | 8' |
| D2 | .290 | - | 7.37 | - | aaa | .004 | | 0.10 | |
| D3 | .016 | .024 | 0.41 | 0.61 | | | | | |
| E | .316 | .324 | 8.03 | 8.23 | | | | | |
| E1 | .238 | .242 | 6.04 | 6.15 | | | | | |
| E2 | .066 | .074 | 1.68 | 1.88 | | | | | |
| E3 | .150 | - | 3.81 | - | | | | | |
| E4 | .058 | .066 | 1.47 | 1.68 | | | | | |
| E5 | .231 | .235 | 5.87 | 5.97 | | | | | |
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| TITLE: TO-270 GULL WING | | | | | DOCUMENT NO: 98ASA99301D | | | REV: C | |
| | | | | | CASE NUMBER: 1265A-03 | | | 02 JUL 2007 | |
| | | | | | STANDARD: JEDEC TO-270 BA | | | | |

PRODUCT DOCUMENTATION, SOFTWARE AND TOOLS

Refer to the following documents, software and tools to aid your design process.

Application Notes

- AN1907: Solder Reflow Attach Method for High Power RF Devices in Over-Molded Plastic Packages
- AN1955: Thermal Measurement Methodology of RF Power Amplifiers
- AN3789: Clamping of High Power RF Transistors and RFICs in Over-Molded Plastic Packages

Engineering Bulletins

- EB212: Using Data Sheet Impedances for RF LDMOS Devices

Software

- Electromigration MTTF Calculator
- RF High Power Model
- .s2p File

Development Tools

- Printed Circuit Boards

For Software and Tools, do a Part Number search at <http://www.freescale.com>, and select the “Part Number” link. Go to the Software & Tools tab on the part’s Product Summary page to download the respective tool.

REVISION HISTORY

The following table summarizes revisions to this document.

| Revision | Date | Description |
|----------|-----------|--|
| 0 | June 2012 | <ul style="list-style-type: none"> • Initial Release of Data Sheet |
| 1 | Apr. 2013 | <ul style="list-style-type: none"> • Load Mismatch/Ruggedness tables: changed output power to input power to clarify the conditions used during test, p. 1, 3, 14, 20 • Added 136–174 MHz VHF Broadband Reference Circuit as follows: <ul style="list-style-type: none"> - Typical Performance table, p. 1 - Table 8, VHF Broadband Performance, p. 8 - Table 9, Load Mismatch/Ruggedness, p. 8 - Fig. 10, VHF Broadband Reference Circuit Component Layout, p. 9 - Table 10, VHF Broadband Reference Circuit Component Designations and Values, p. 9 - Fig. 11, VHF Broadband Reference Circuit Schematic, p. 10 - Table 11, VHF Broadband Reference Circuit Microstrips, p. 10 - Fig. 12, Power Gain, Drain Efficiency and Output Power versus Frequency at a Constant Input Power – 12.5 V, p. 11 - Fig. 13, Power Gain, Drain Efficiency and Output Power versus Frequency at a Constant Input Power – 13.6 V, p. 11 - Fig. 14, Output Power versus Gate–Source Voltage, p. 12 - Fig. 15, Power Gain, Output Power and Drain Efficiency versus Input Power and Frequency, p. 12 - Fig. 16, VHF Broadband Series Equivalent Source and Load Impedance, p. 13 • Figs. 10, 17 and 24, Reference Circuit Component Layouts: added manufacturer part number, p. 9, 15, 21 • Fig. 23, UHF Broadband Series Equivalent Source and Load Impedance — 380–450 MHz: corrected bias measurement from 10 mA to 100 mA, p. 19 |

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